

## 200 mA 42 V Ultra Low Supply Current Voltage Regulator

No. EA-520-230703

### OVERVIEW

The R1525x is a low supply current voltage regulator featuring 200 mA output current and up to 42 V input voltage. By providing excellent noise immunity, this device is suitable for the power source for control unit used under the electromagnetic environment.

### KEY BENEFITS

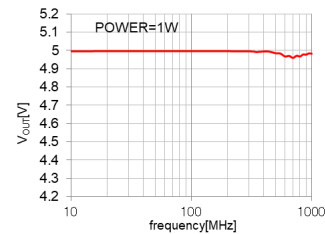
- Achieves low-supply current of 2.2µA (Typ.) with the LDO at maximum rating 50 V (Peak Inrush Voltage: 60 V).
- Ensures the design margin by the output voltage with high-accuracy of ±0.6% (Ta=25°C).
- Protects the output voltage variations in high-frequency noise band (10MHz to 1GHz).

### KEY SPECIFICATIONS

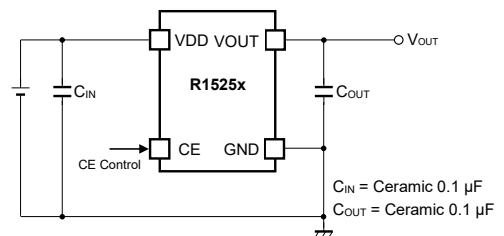
- Input Voltage Range: 3.5 V to 42.0 V
- Maximum Rating: 50 V  
(Peak Inrush Voltage: 60 V@200ms or less)
- Operating Temperature Range: -40°C to 105°C
- Supply Current: Typ. 2.2 µA (Typ. 0.1 µA at Standby)
- Dropout Voltage: Typ. 0.6 V (I<sub>OUT</sub> = 200 mA, V<sub>OUT</sub> = 5.0 V)
- Output Voltage Range: 1.8 V, 2.5 V, 2.8 V, 3.0 V, 3.3 V, 3.4 V, 5.0 V, 5.5 V, 6.0 V, 6.4 V, 8.0 V, 8.5 V, 9.0 V, 10.0 V, 10.5 V, 11.0 V, 12.0 V
- Output Voltage Accuracy: ±0.6% (Ta = 25°C)  
±1.6% (-40°C ≤ Ta ≤ 105°C)
- Input Stability: Typ. 0.01%/V (V<sub>SET</sub> + 1 V ≤ V<sub>IN</sub> ≤ 42 V)
- Short-circuit Protection: Limited to Typ. 80 mA
- Overcurrent Protection: Limited to Typ. 350 mA
- Thermal Shutdown: Detected at Typ.160°C

### CHARACTERISTICS

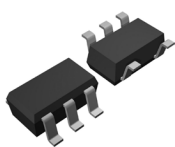
Noise Immunity Characteristic



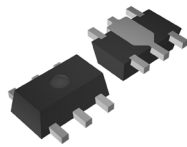
### TYPICAL APPLICATIONS



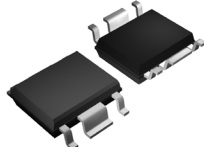
### PACKAGES (Unit: mm)



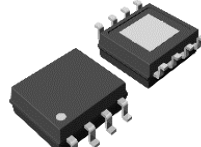
**SOT-23-5**  
2.9 x 2.8 x 1.1



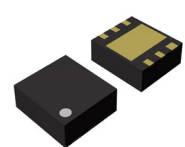
**SOT-89-5**  
4.5 x 4.35 x 1.5



**HSOP-6J**  
5.02 x 6.0 x 1.5



**HSOP-8E**  
5.2 x 6.2 x 1.45



**DFN(PL)1820-6**  
1.8 x 2.0 x 0.6

### APPLICATIONS

- Power source for home appliances such as refrigerators, rice cookers, and electric hot-water pot.
- Power source for notebook PCs, digital TVs, cordless phones, and private LAN system.
- Power source for office equipment machines such as copiers, printers, facsimiles, scanners, and projectors.

## SELECTION GUIDE

The set output voltage and the package type are user-selectable.

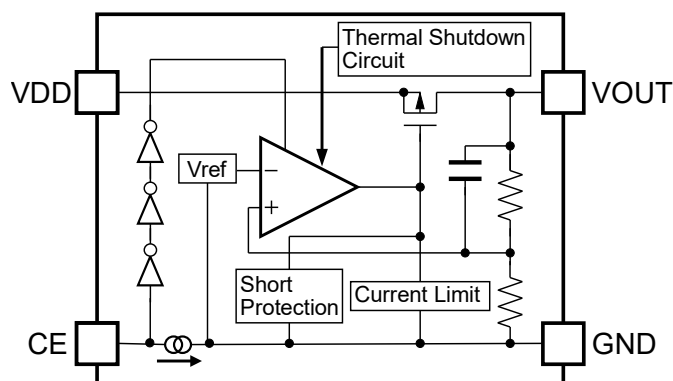
### Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1525NxxxB-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes
R1525HxxxB-T1-FE	SOT-89-5	1,000 pcs	Yes	Yes
R1525SxxxB-E2-FE	HSOP-6J	1,000 pcs	Yes	Yes
R1525SxxxH-E2-FE	HSOP-8E	1,000 pcs	Yes	Yes
R1525KxxxB-TR	DFN(PL)1820-6	5,000 pcs	Yes	Yes

xxx : Specify the set output voltage ( $V_{SET}$ )

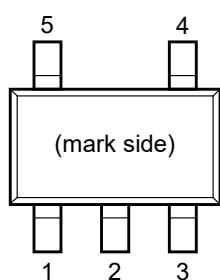
1.8 V (018) / 2.5 V (025) / 2.8 V (028) / 3.0 V (030) / 3.3 V (033) / 3.4 V (034) / 5.0 V (050) /  
5.5 V (055) / 6.0 V (060) / 6.4 V (064) / 8.0 V (080) / 8.5 V (085) / 9.0 V (090) / 10.0 V (100) /  
10.5V (105) / 11.0 V (110) / 12.0 V (120)

## BLOCK DIAGRAM

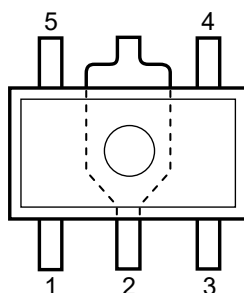


R1525x Block Diagram

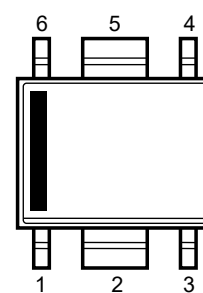
## PIN DESCRIPTIONS



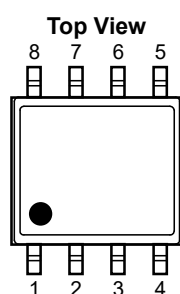
**R1525N (SOT-23-5)  
Pin Configuration**



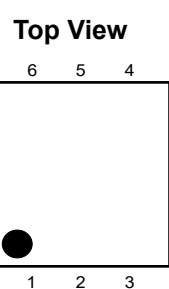
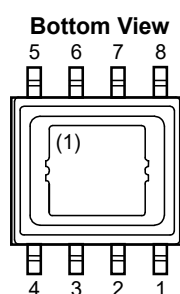
**R1525H (SOT-89-5)  
Pin Configuration**



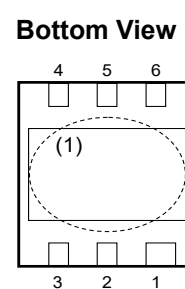
**R1525S (HSOP-6J)  
Pin Configuration**



**R1525S (HSOP-8E) Pin Configuration**



**R1525K (DFN(PL)1820-6) Pin Configuration**



## R1525N Pin Description

Pin No.	Pin Name	Description
1	GND <sup>(2)</sup>	Ground Pin
2	GND <sup>(2)</sup>	Ground Pin
3	CE	Chip Enable Pin (Active-high)
4	VOUT	Output Pin
5	VDD	Input Pin

## R1525H Pin Description

Pin No.	Pin Name	Description
1	VOUT	Output Pin
2	GND <sup>(2)</sup>	Ground Pin
3	CE	Chip Enable Pin (Active-high)
4	GND <sup>(2)</sup>	Ground Pin
5	VDD	Input Pin

<sup>(1)</sup> The tab on the bottom of the package enhances thermal performance and is electrically connected to GND (substrate level). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left open.

<sup>(2)</sup> The GND pin must be wired together when it is mounted on board.

**R1525S (HSOP-6J) Pin Description**

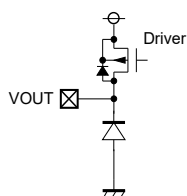
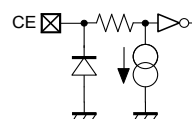
Pin No.	Pin Name	Description
1	VOUT	Output Pin
2	GND <sup>(1)</sup>	Ground Pin
3	CE	Chip Enable Pin (Active-high)
4	GND <sup>(1)</sup>	Ground Pin
5	GND <sup>(1)</sup>	Ground Pin
6	VDD	Input Pin

**R1525S (HSOP-8E) Pin Description**

Pin No.	Pin Name	Description
1	VOUT	Output Pin
2	NC	No Connection
3	NC	No Connection
4	CE	Chip Enable Pin (Active-high)
5	GND	Ground Pin
6	NC	No Connection
7	NC	No Connection
8	VDD	Input Pin

**R1525K (DFN(PL)1820-6) Pin Description**

Pin No.	Pin Name	Description
1	CE	Chip Enable Pin (Active-high)
2	NC	No Connection
3	GND	Ground Pin
4	VDD	Input Pin
5	NC	No Connection
6	VOUT	Output Pin

**Pin Equivalent Circuit Diagrams****VOUT Pin Equivalent Circuit Diagram****CE Pin Equivalent Circuit Diagram**<sup>(1)</sup> The GND pins are connected to each other on the board.

## ABSOLUTE MAXIMUM RATINGS

### Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit	
$V_{IN}$	Input Voltage	-0.3 to 50	V	
$V_{IN}$	Peak Inrush Voltage <sup>(1)</sup>	60	V	
$V_{CE}$	CE Pin Input Voltage	-0.3 to 50	V	
$V_{OUT}$	Output Voltage	-0.3 to $V_{IN} + 0.3 \leq 50$	V	
$I_{OUT}$	Output Current	300	mA	
$P_D$	Power Dissipation <sup>(2)</sup> (JEDEC STD. 51-7)	SOT-23-5	660	mW
		SOT-89-5	2600	
		HSOP-6J	2700	
		HSOP-8E	2900	
		DFN(PL)1820-6	2200	
$T_j$	Junction Temperature	-40 to 125	°C	
$T_{stg}$	Storage Temperature Range	-55 to 125	°C	

### ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

## RECOMMENDED OPERATING CONDITIONS

### Recommended Operating Conditions

Symbol	Parameter	Rating	Unit
$V_{IN}$	Input Voltage	3.5 to 42	V
$T_a$	Operating Temperature Range	-40 to 105	°C

### RECOMMENDED OPERATING CONDITONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

<sup>(1)</sup> Duration: 200 ms or less

<sup>(2)</sup> Refer to *POWER DISSIPATION* for detailed information.

## ELECTRICAL CHARACTERISTICS

$C_{IN} = C_{OUT} = 0.1 \mu\text{F}$ , unless otherwise noted.

The specifications surrounded by   are guaranteed by design engineering at  $-40^\circ\text{C} \leq T_a \leq 105^\circ\text{C}$ .

### R1525x Electrical Characteristics

( $T_a = 25^\circ\text{C}$ )

Symbol	Parameter	Conditions		Min.	Typ.	Max.	Unit
$I_{SS}$	Supply Current	$V_{IN} = 14 \text{ V}$ $I_{OUT} = 0 \text{ mA}$	$V_{SET} \leq 5.0 \text{ V}$		2.2	<span style="border: 1px solid black; padding: 0 2px;">6.5</span>	$\mu\text{A}$
			$5.0 \text{ V} < V_{SET}$		2.5	<span style="border: 1px solid black; padding: 0 2px;">6.8</span>	
$I_{standby}$	Supply Current	$V_{IN} = 42 \text{ V}, V_{CE} = 0 \text{ V}$			0.1	1.0	$\mu\text{A}$
$V_{OUT}$	Output Voltage	$V_{SET} + 1 \text{ V}^{(1)} \leq V_{IN} \leq 42 \text{ V}, I_{OUT} = 1 \text{ mA}$	$T_a = 25^\circ\text{C}$	$\times 0.994$		$\times 1.006$	V
			$-40^\circ\text{C} \leq T_a \leq 105^\circ\text{C}$	<span style="border: 1px solid black; padding: 0 2px;"><math>\times 0.984</math></span>		<span style="border: 1px solid black; padding: 0 2px;"><math>\times 1.016</math></span>	
$\Delta V_{OUT} / \Delta I_{OUT}$	Load Regulation	$V_{IN} = V_{SET} + 3.0 \text{ V}$ $1 \text{ mA} \leq I_{OUT} \leq 200 \text{ mA}$		Refer to Product-specific Electrical Characteristics			
$\Delta V_{OUT} / \Delta V_{IN}$	Line Regulation	$V_{SET} + 1 \text{ V}^{(1)} \leq V_{IN} \leq 42 \text{ V}, I_{OUT} = 1 \text{ mA}$	$V_{SET} < 3.3 \text{ V}$	<span style="border: 1px solid black; padding: 0 2px;">-20</span>	5	<span style="border: 1px solid black; padding: 0 2px;">20</span>	mV
			$3.3 \text{ V} \leq V_{SET}$	<span style="border: 1px solid black; padding: 0 2px;">-0.02</span>	0.01	<span style="border: 1px solid black; padding: 0 2px;">0.02</span>	%/V
$V_{DIF}$	Dropout Voltage	$I_{OUT} = 200 \text{ mA}$		Refer to Product-specific Electrical Characteristics			
$I_{LIM}$	Output Current Limit	$V_{IN} = V_{SET} + 3.0 \text{ V}$		<span style="border: 1px solid black; padding: 0 2px;">220</span>	350	<span style="border: 1px solid black; padding: 0 2px;">420</span>	mA
$I_{SC}$	Short-circuit Current	$V_{IN} = 3.5 \text{ V}, V_{OUT} = 0 \text{ V}$		<span style="border: 1px solid black; padding: 0 2px;">60</span>	80	<span style="border: 1px solid black; padding: 0 2px;">110</span>	mA
$V_{CEH}$	CE Pin Input Voltage, high	$V_{IN} = V_{SET} + 1 \text{ V}^{(1)}$		<span style="border: 1px solid black; padding: 0 2px;">2.0</span>		42	V
$V_{CEL}$	CE Pin Input Voltage, low	$V_{IN} = 42 \text{ V}$		0		<span style="border: 1px solid black; padding: 0 2px;">1.0</span>	V
$I_{PD}$	CE Pull-down Current	$V_{IN} = 42 \text{ V}, V_{CE} = 2 \text{ V}$			0.2	<span style="border: 1px solid black; padding: 0 2px;">0.6</span>	$\mu\text{A}$
$T_{TSD}$	Thermal Shutdown Detection Temperature	Junction Temperature			160		$^\circ\text{C}$
$T_{TSR}$	Thermal Shutdown Release Temperature	Junction Temperature			135		$^\circ\text{C}$

All parameters are tested under the pulse load condition ( $T_j \approx T_a = 25^\circ\text{C}$ ).

<sup>(1)</sup>  $V_{SET} \leq 2.5 \text{ V}, V_{IN} = 3.5 \text{ V}$

The specifications surrounded by  $\square$  are guaranteed by design engineering at  $-40^{\circ}\text{C} \leq T_a \leq 105^{\circ}\text{C}$ .

## R1525x Product-specific Electrical Characteristics

(Ta = 25°C)

Product Name	V <sub>OUT</sub> (V) (Ta = 25°C)			V <sub>OUT</sub> (V) (-40°C ≤ Ta ≤ 105°C)			ΔV <sub>OUT</sub> /ΔI <sub>OUT</sub> (mV)			V <sub>DIF</sub> (V)	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	TYP.	MAX.
R1525x018x	1.7892	1.80	1.8108	$\square$ 1.7712	1.80	$\square$ 1.8288	$\square$ -10	10	$\square$ 40	1.6	$\square$ 2.5
R1525x025x	2.4850	2.50	2.5150	$\square$ 2.4600	2.50	$\square$ 2.5400				1.2	$\square$ 2.2
R1525x028x	2.7832	2.80	2.8168	$\square$ 2.7552	2.80	$\square$ 2.8448					
R1525x030x	2.9820	3.00	3.0180	$\square$ 2.9520	3.00	$\square$ 3.0480				0.8	$\square$ 2.0
R1525x033x	3.2802	3.30	3.3198	$\square$ 3.2472	3.30	$\square$ 3.3528					
R1525x034x	3.3796	3.40	3.4204	$\square$ 3.3456	3.40	$\square$ 3.4544					
R1525x050x	4.9700	5.00	5.0300	$\square$ 4.9200	5.00	$\square$ 5.0800				$\square$ -18	18
R1525x055x	5.4670	5.50	5.5330	$\square$ 5.4120	5.50	$\square$ 5.5880					
R1525x060x	5.9640	6.00	6.0360	$\square$ 5.9040	6.00	$\square$ 6.0960					
R1525x064x	6.3616	6.40	6.4384	$\square$ 6.2976	6.40	$\square$ 6.5024	0.5				
R1525x080x	7.9520	8.00	8.0480	$\square$ 7.8720	8.00	$\square$ 8.1280					
R1525x085x	8.4490	8.50	8.5510	$\square$ 8.3640	8.50	$\square$ 8.6360					
R1525x090x	8.9460	9.00	9.0540	$\square$ 8.8560	9.00	$\square$ 9.1440					
R1525x100x	9.9400	10.0	10.0600	$\square$ 9.8400	10.0	$\square$ 10.1600					
R1525x105x	10.4370	10.5	10.5630	$\square$ 10.3320	10.5	$\square$ 10.6680					
R1525x110x	10.9340	11.0	11.0660	$\square$ 10.8240	11.0	$\square$ 11.1760					
R1525x120x	11.9280	12.0	12.0720	$\square$ 11.8080	12.0	$\square$ 12.1920					

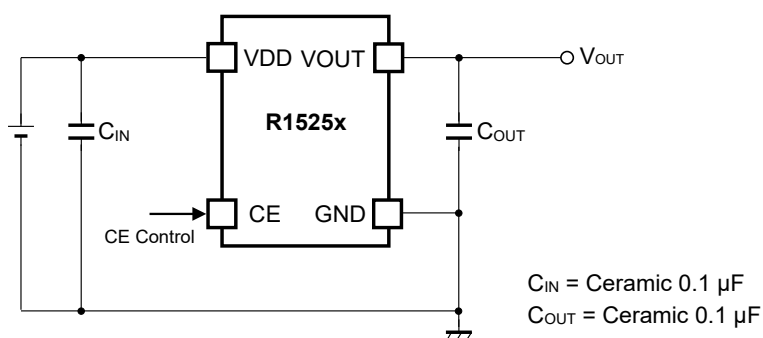
## THEORY OF OPERATION

### Thermal Shutdown

When the junction temperature of this device exceeds 160°C (Typ.), the built-in thermal shutdown circuit stops the regulator operation. After that, when the temperature drops to 135°C (Typ.) or lower, the regulator restarts the operation. Unless eliminating the overheating problem, the regulator turns on and off repeatedly and a pulse shaped output voltage occurs as result.

## APPLICATION INFORMATION

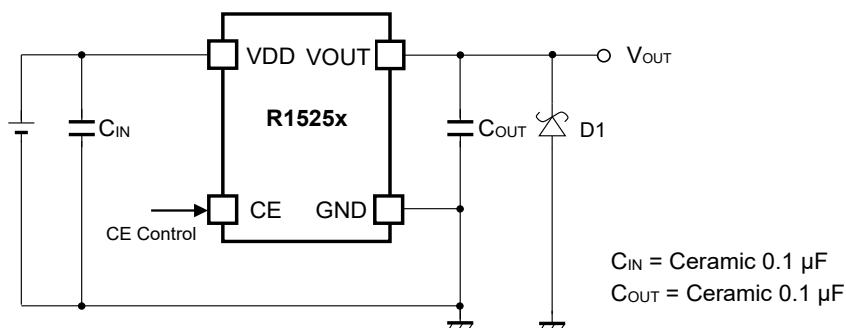
### Typical Applications



**R1525x Typical Applications**

### Typical Application for IC Chip Breakdown Prevention

When a sudden surge of electrical current travels along the VOUT pin and GND due to a short-circuit, electrical resonance of a circuit involving an output capacitor and a short circuit inductor generates a negative voltage and may damage the device or the load devices. Connecting a schottky diode (D1) between the VOUT pin and GND has the effect of preventing damage to them.



**R1525x Typical Application for IC Chip Breakdown Prevention**



## TECHNICAL NOTES

### Phase Compensation

Phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, make sure to use 0.1  $\mu\text{F}$  or more of a capacitor ( $C_{\text{OUT}}$ ). In case of using a tantalum type capacitor and the ESR (Equivalent Series Resistance) value of the capacitor is large, the output might be unstable. Evaluate the circuit including consideration of frequency characteristics. Connect 0.1  $\mu\text{F}$  or more of a capacitor ( $C_{\text{IN}}$ ) between VDD and GND, and as close as possible to the pins.

### PCB Layout

For SOT-23-5 package type, wire the following GND pins together: No. 1 and No. 2

For SOT-89-5 package type, wire the following GND pins together: No. 2 and No. 4.

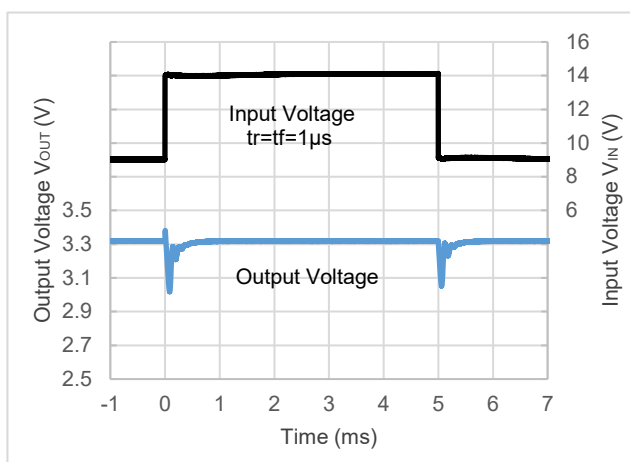
For HSOP-6J package type, wire the following GND pins together: No. 2, No. 4, and No. 5.

## Input Transient / Load Transient vs. Output Capacity ( $C_{OUT}$ )

R1525x performs a stable operation by using 0.1  $\mu\text{F}$  of ceramic capacitor as the output capacitor. However, the variation of output voltage may not meet the demand of the system when input voltage and load current vary. In such cases, the variation of output voltage can be minimized significantly by using 10  $\mu\text{F}$  or higher ceramic capacitor. When using an electrolytic capacitor for the output line, place the electrolytic capacitor outer side of the ceramic capacitor arranged close to the IC.

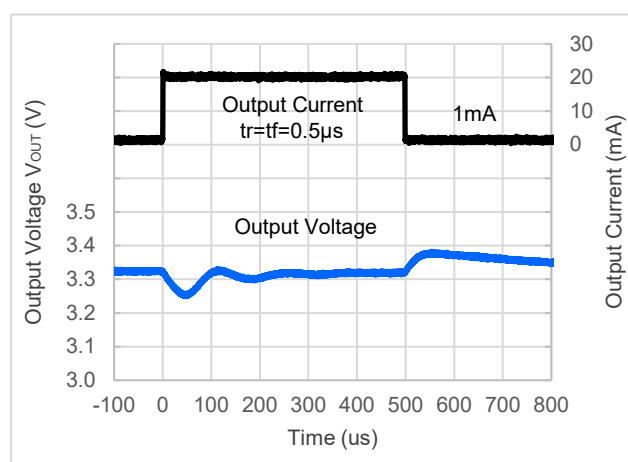
### <Input Transient Response>

R1525x033B



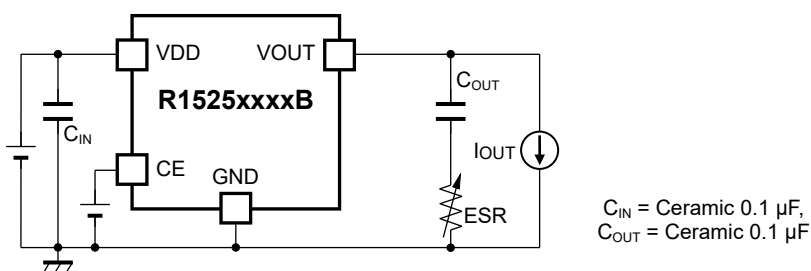
### <Load Transient Response>

R1525x033B

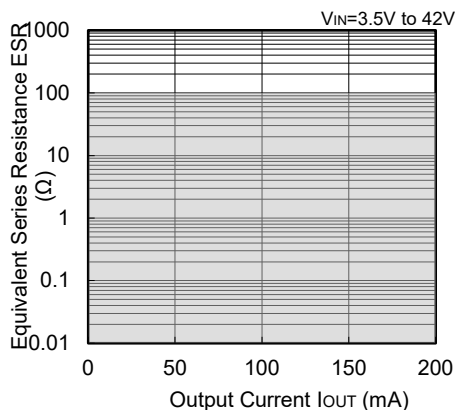


## ESR vs. Output Current

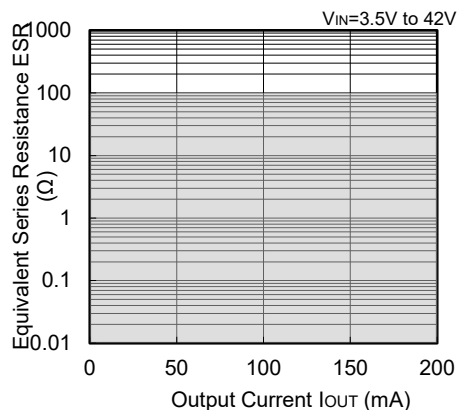
Using a ceramic type capacitor is recommended for this device, but also other type capacitors having lower ESR can be used. The relation between the output current ( $I_{OUT}$ ) and the ESR of output capacitor is shown below.



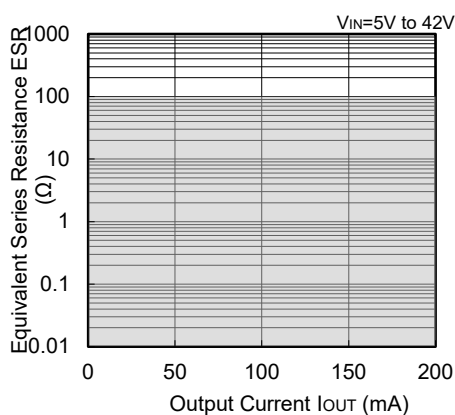
**R1525x018B**



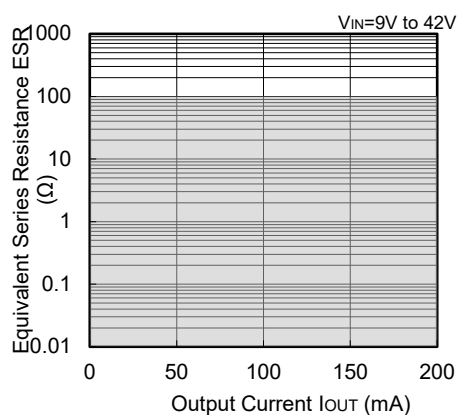
**R1525x033B**



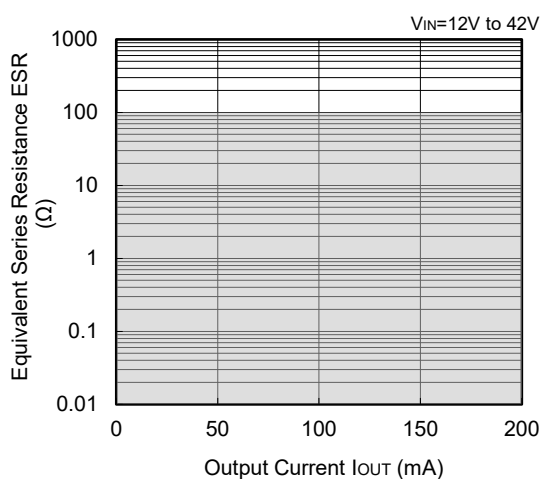
**R1525x050B**



**R1525x090B**



**R1525x120B**



**Measurement Conditions**

Frequency Band: 10 Hz to 2 MHz

Measurement Temperature: -40°C to 105°C

Noise Level in Hatched Area:  
40 μV (average) or below

Ceramic Capacitors:

C<sub>IN</sub> = 0.1 μF, Murata, GRM188R71H104JA93D

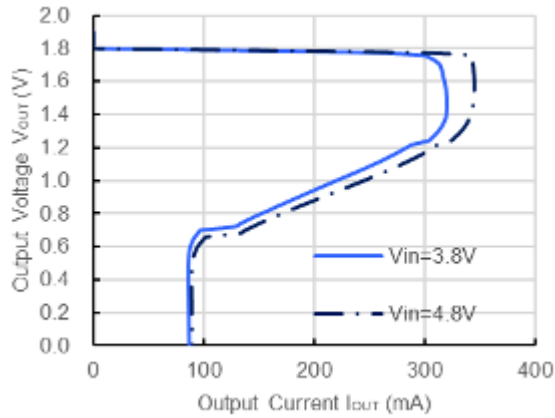
C<sub>OUT</sub> = 0.1 μF, TDK, CGA3E2X7R1E104K

## TYPICAL CHARACTERISTICS

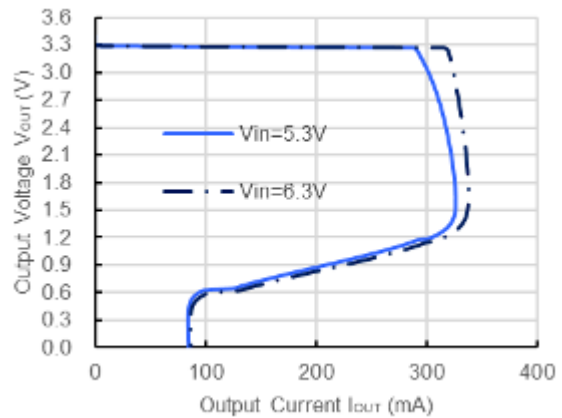
Typical Characteristics are intended to be used as reference data, they are not guaranteed.

### 1) Output Voltage vs. Output Current

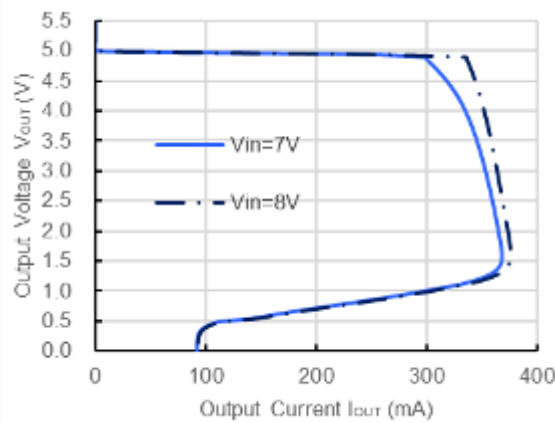
R1525x018B



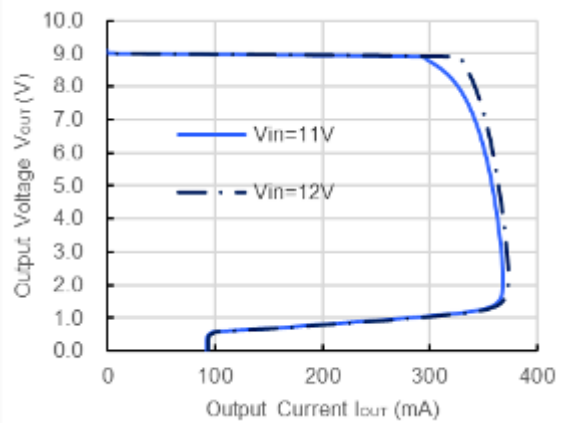
R1525x033B



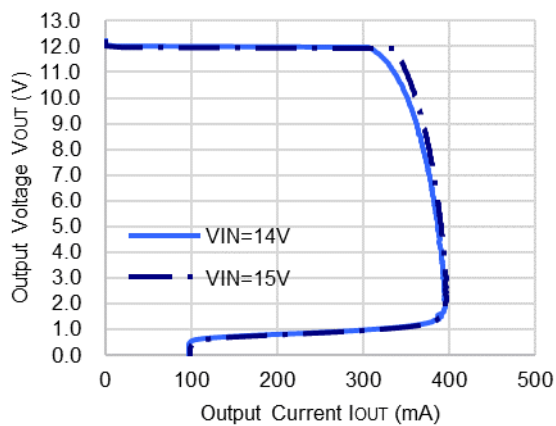
R1525x050B



R1525x090B

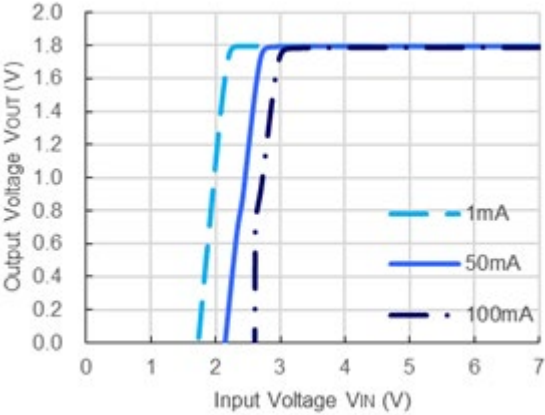


R1525x120B

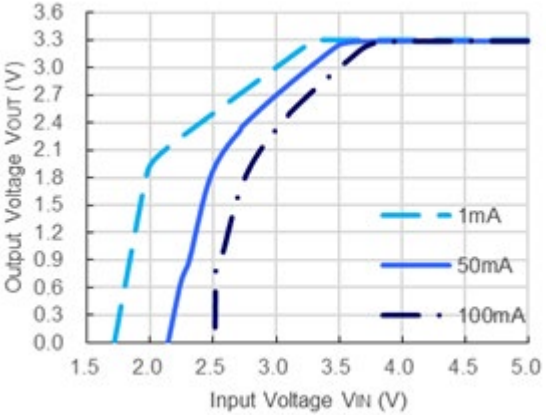


2) Output Voltage vs. Input Voltage

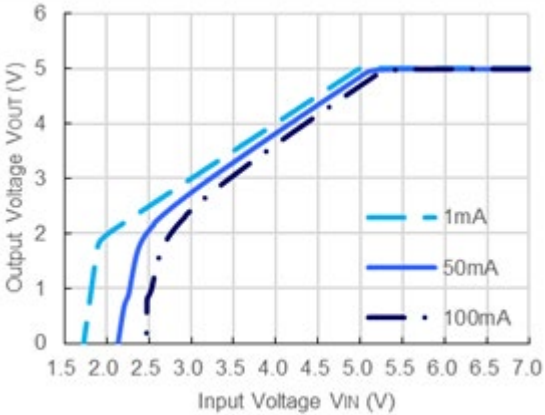
R1525x018B



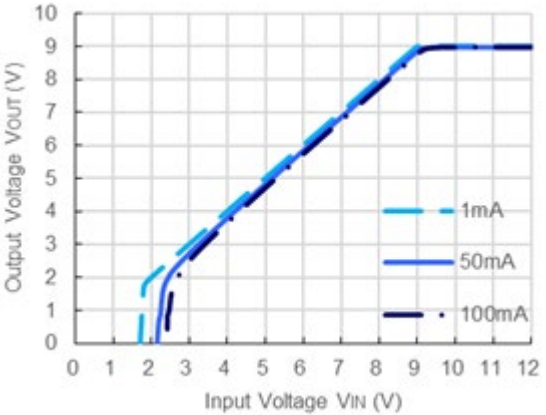
R1525x033B



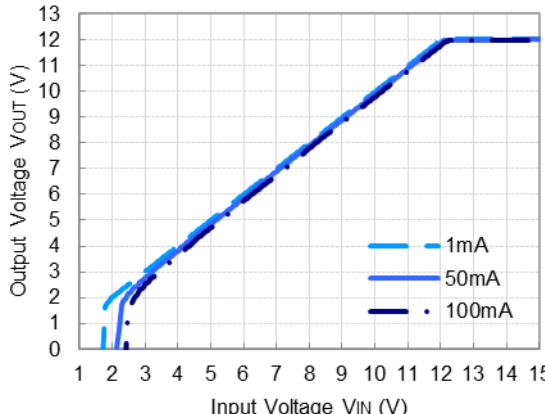
R1525x050B



R1525x090B

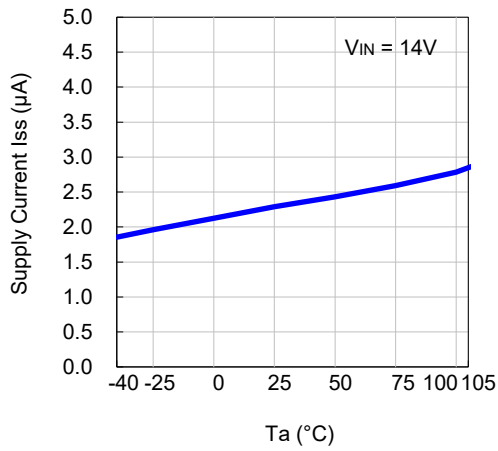


R1525x120B

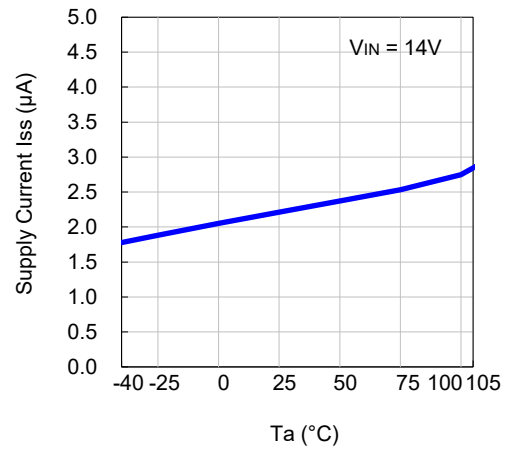


3) Supply Current vs. Temperature

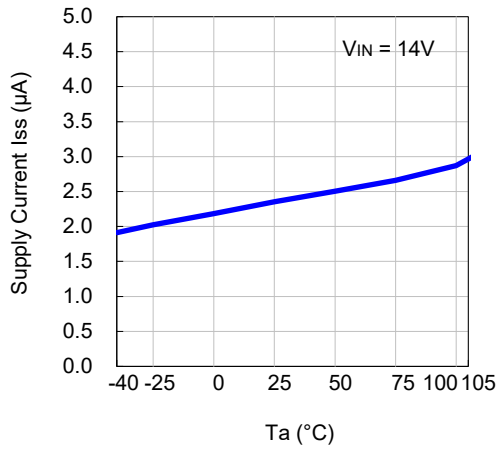
R1525x018B



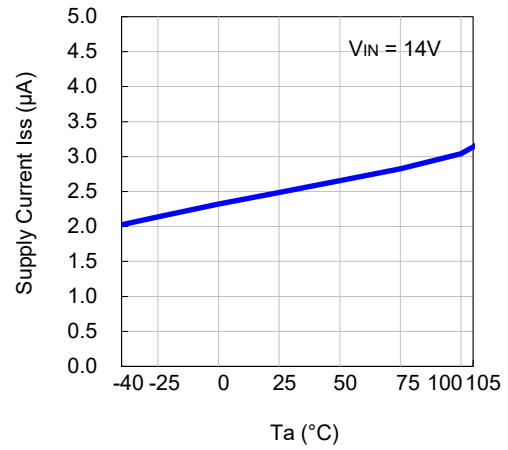
R1525x033B



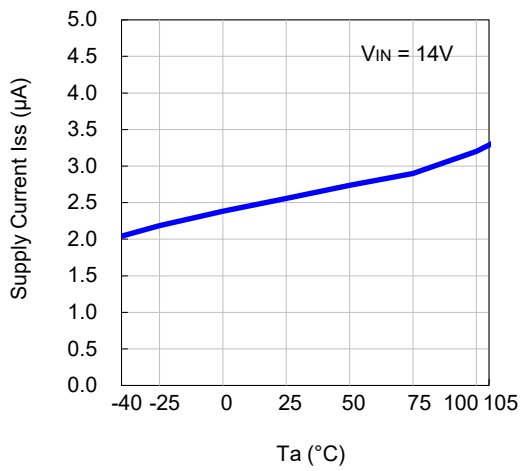
R1525x050B



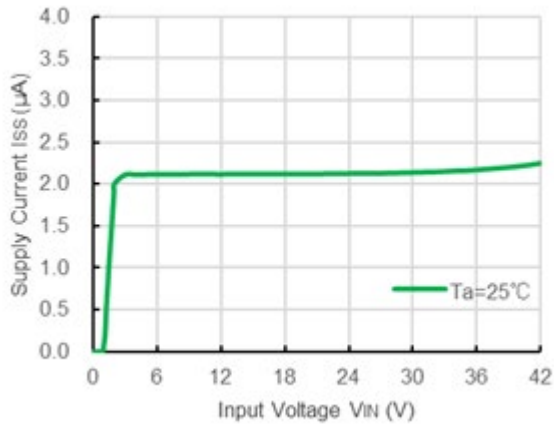
R1525x090B



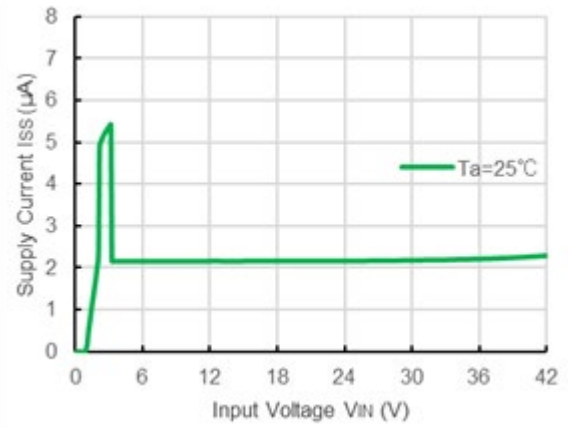
R1525x120B



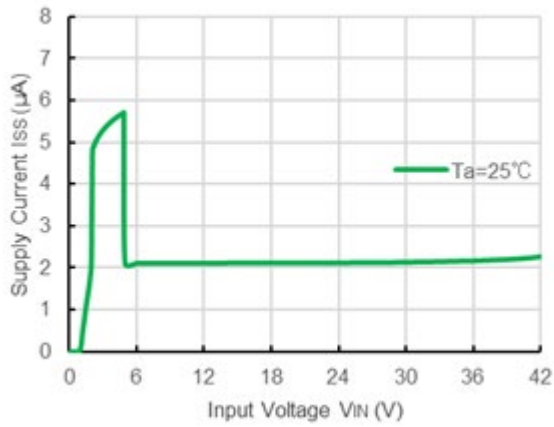
4) Supply Current vs. Input Voltage  
R1525x018B



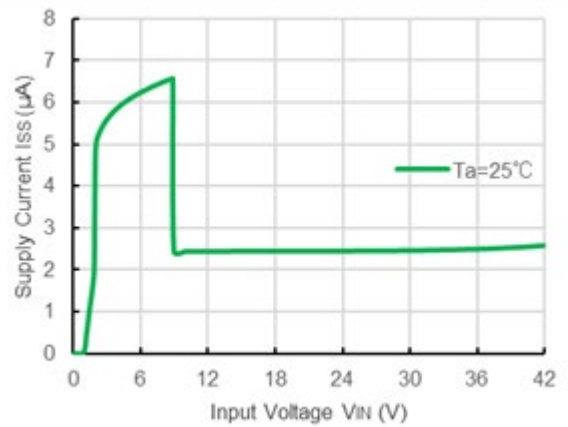
R1525x033B



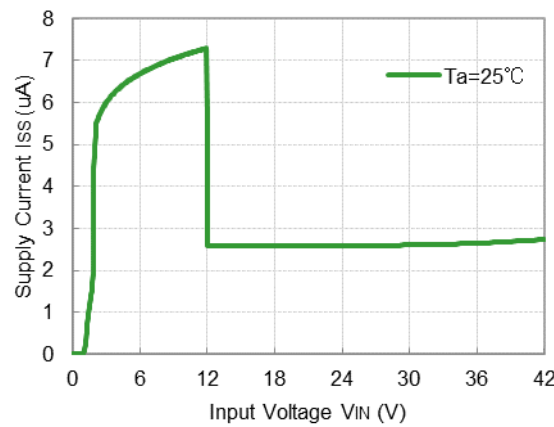
R1525x050B



R1525x090B

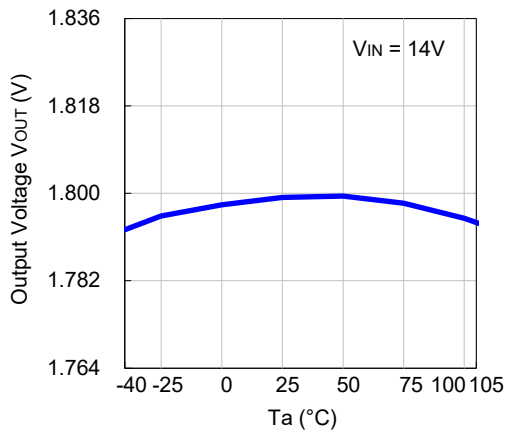


R1525x120B

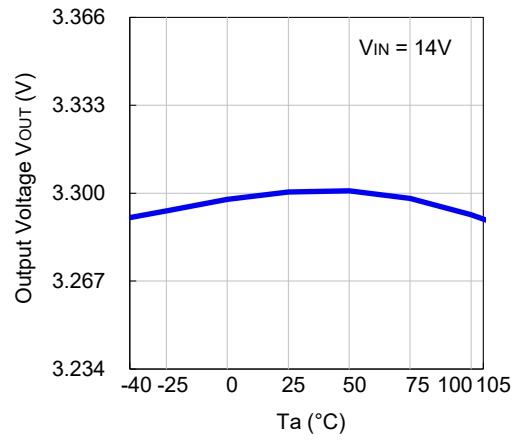


5) Output Voltage vs. Temperature ( $I_{OUT} = 1.0 \text{ mA}$ )

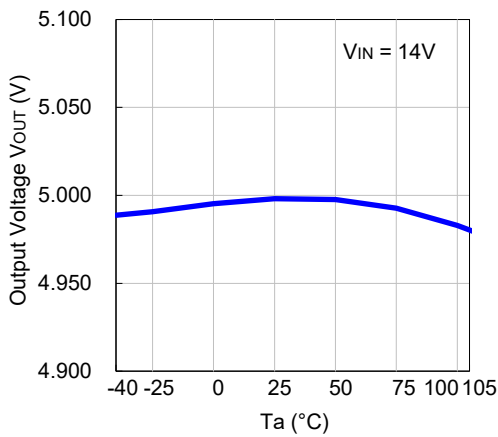
R1525x018B



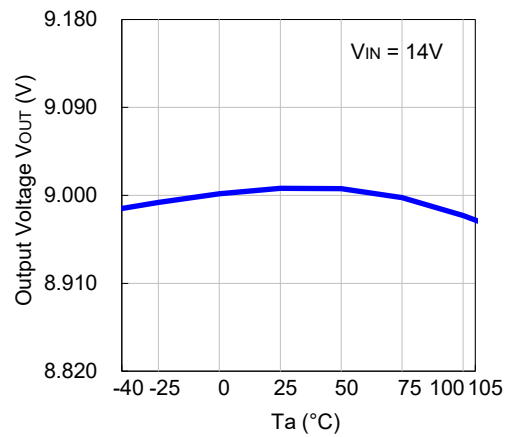
R1525x033B



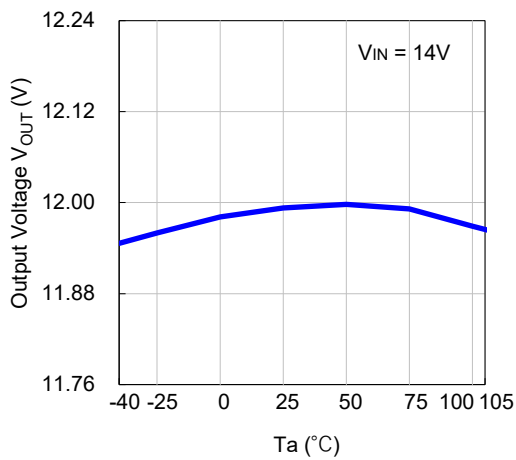
R1525x050B



R1525x090B



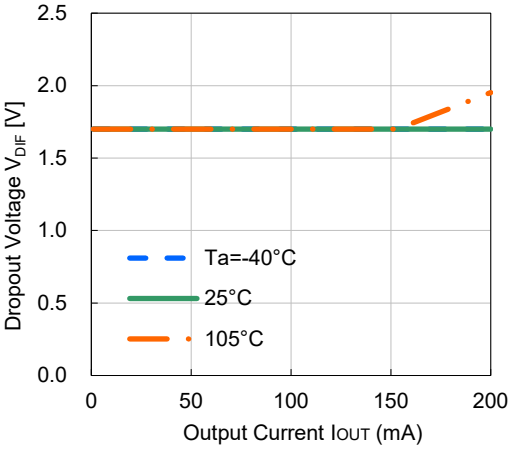
R1525x120B



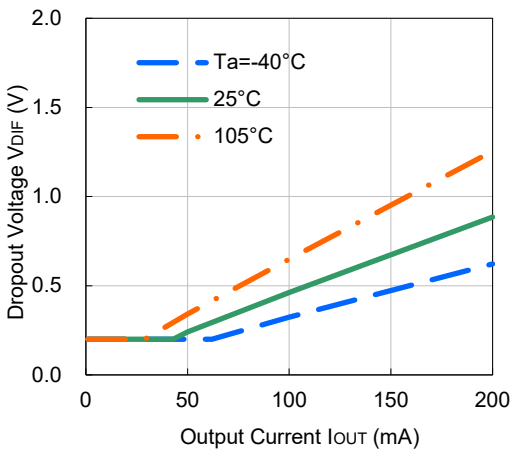


6) Dropout Voltage vs. Output Current

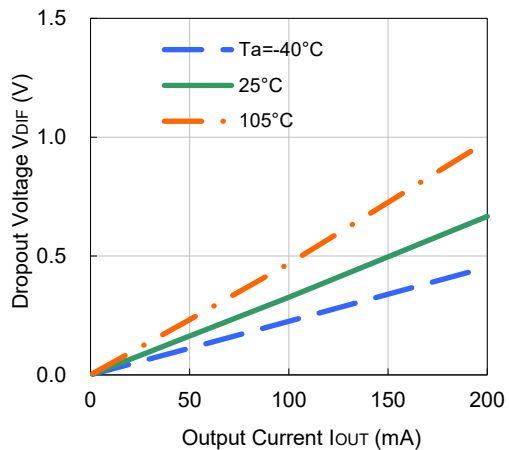
R1525x018B



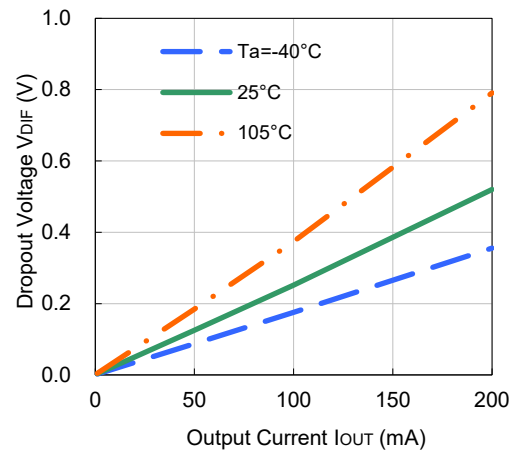
R1525x033B



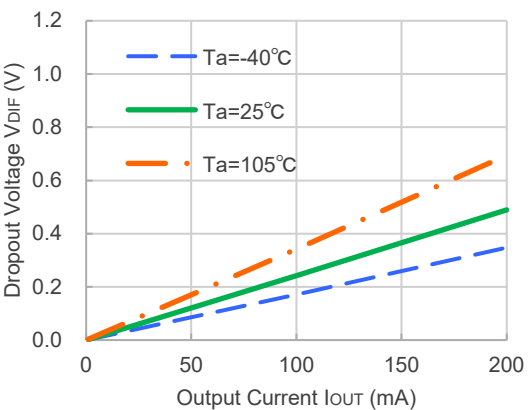
R1525x050B



R1525x090B

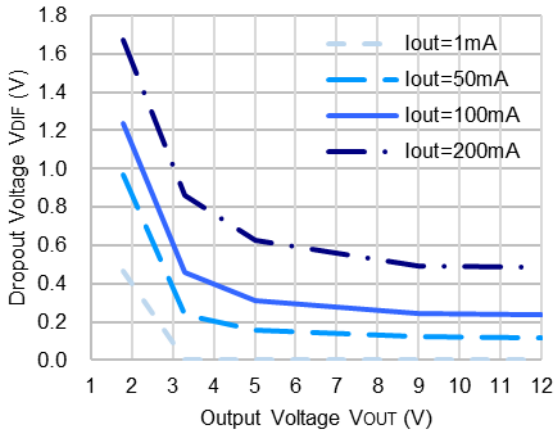


R1525x120B



**7) Dropout Voltage vs. Output Voltage**

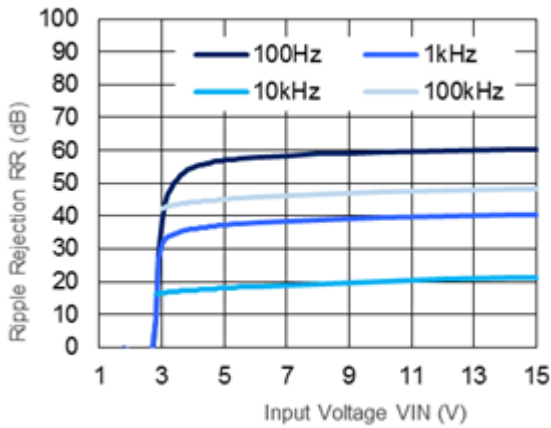
$I_{OUT} = 1\text{ mA} / 50\text{ mA} / 100\text{ mA} / 200\text{ mA}$



**8) Ripple Rejection vs. Input Voltage**

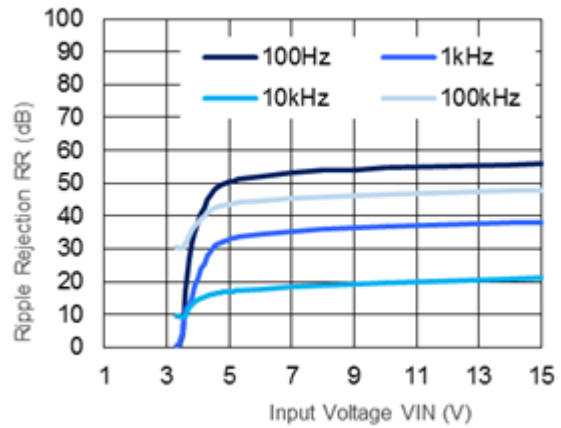
$I_{OUT} = 50\text{ mA}$ ,  $V_{RIPPLE} = \pm 0.2\text{ V}$

R1525x018B



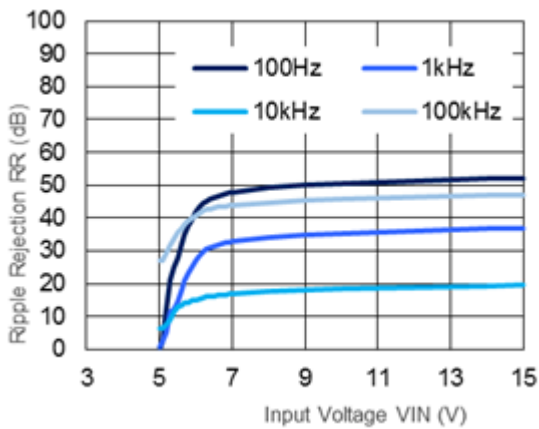
$I_{OUT} = 50\text{ mA}$ ,  $V_{RIPPLE} = \pm 0.2\text{ V}$

R1525x033B



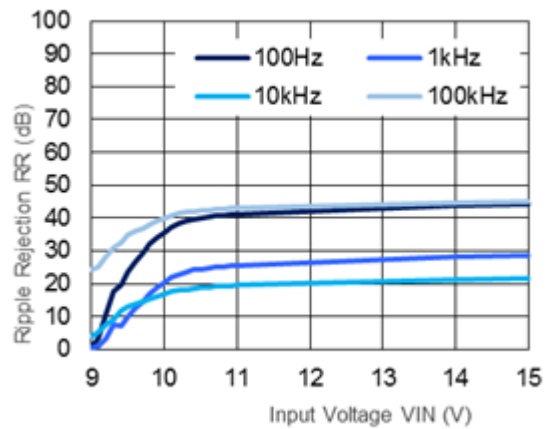
$I_{OUT} = 50\text{ mA}$ ,  $V_{RIPPLE} = \pm 0.2\text{ V}$

R1525x050B



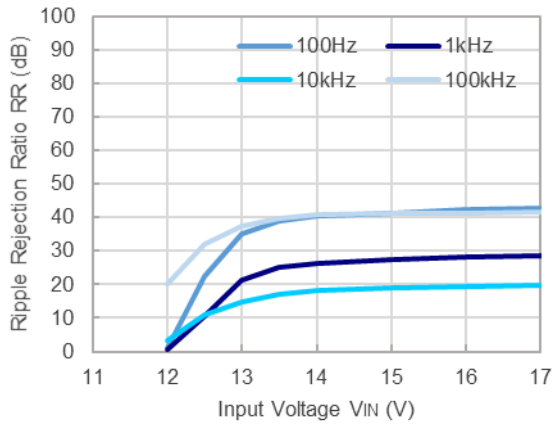
$I_{OUT} = 50\text{ mA}$ ,  $V_{RIPPLE} = \pm 0.2\text{ V}$

R1525x090B



$I_{OUT} = 50\text{ mA}$ ,  $V_{RIPPLE} = \pm 0.2\text{ V}$

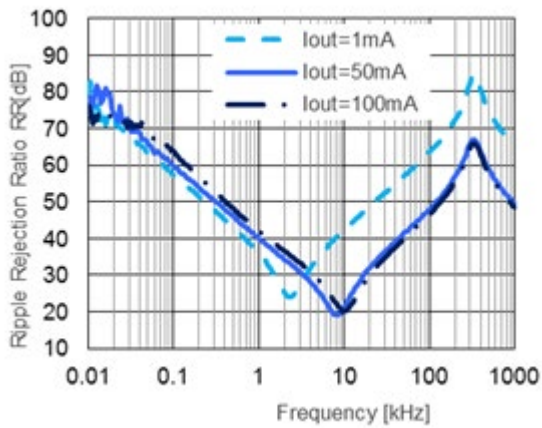
R1525x120B



9) Ripple Rejection vs. Frequency

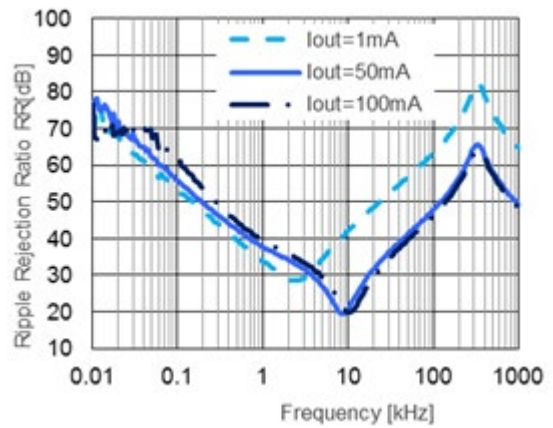
$V_{RIPPLE} = \pm 0.2\text{ V}$

R1525x018B



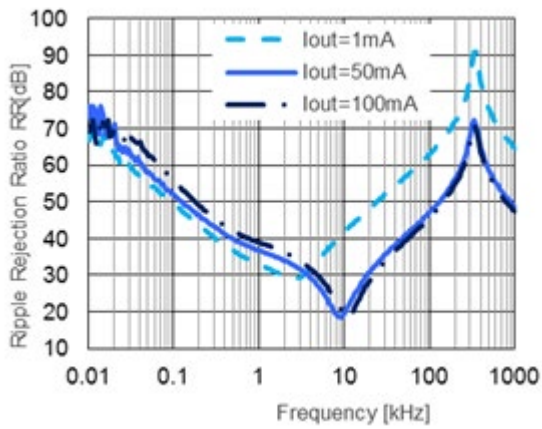
$V_{RIPPLE} = \pm 0.2\text{ V}$

R1525x033B



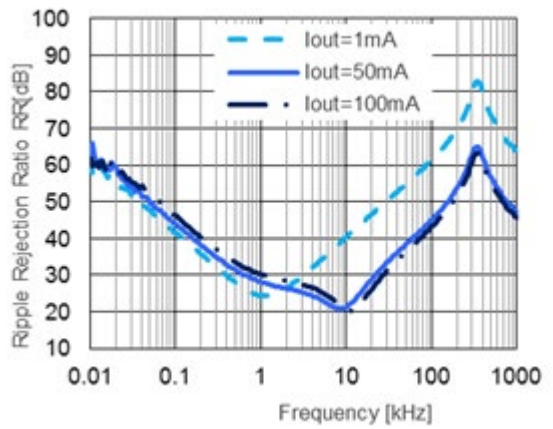
$V_{RIPPLE} = \pm 0.2\text{ V}$

R1525x050B



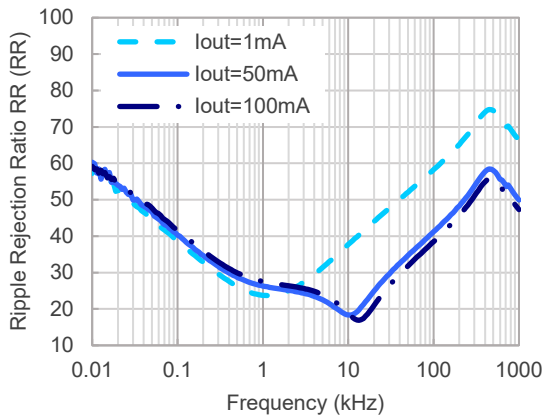
$V_{RIPPLE} = \pm 0.2\text{ V}$

R1525x090B



$V_{\text{RIPPLE}} = \pm 0.2 \text{ V}$

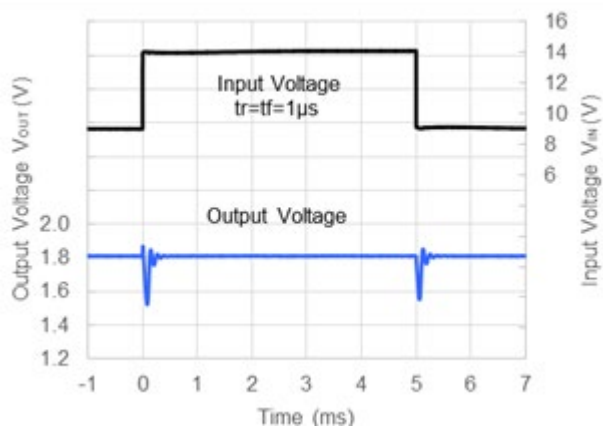
R1525x120B



**10) Input Transient Response**

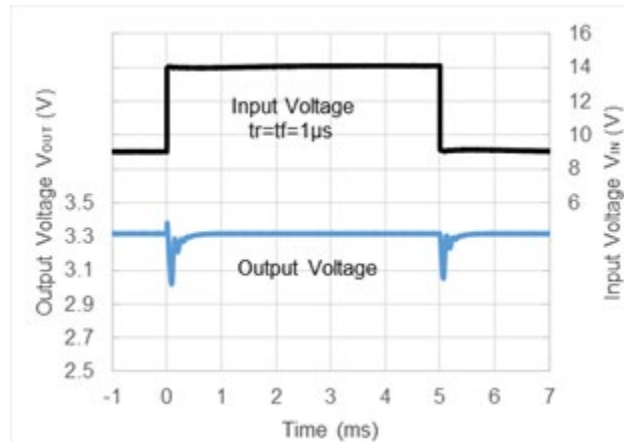
$I_{\text{OUT}} = 50 \text{ mA}$ ,  $C_{\text{OUT}} = 10\mu\text{F}$

R1525x018B



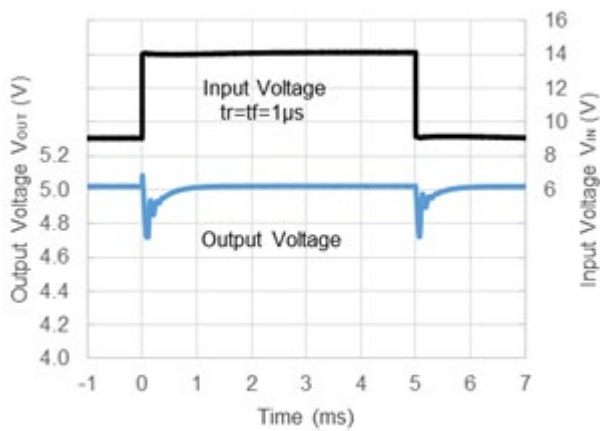
$I_{\text{OUT}} = 50 \text{ mA}$ ,  $C_{\text{OUT}} = 10\mu\text{F}$

R1525x033B



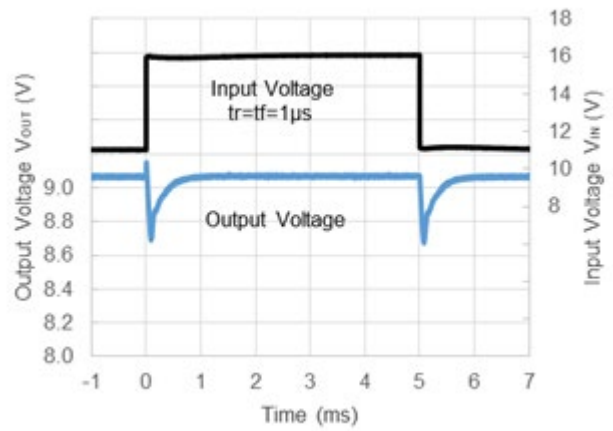
$I_{\text{OUT}} = 50 \text{ mA}$ ,  $C_{\text{OUT}} = 10\mu\text{F}$

R1525x050B

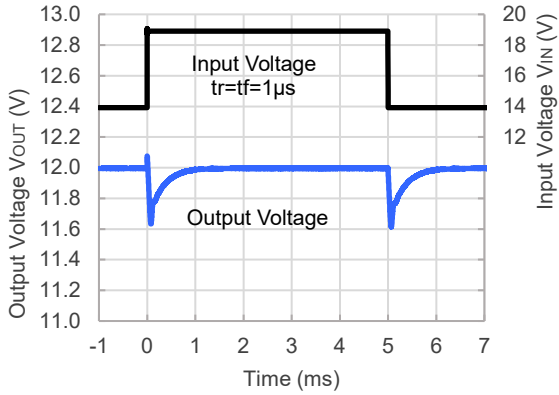


$I_{\text{OUT}} = 50 \text{ mA}$ ,  $C_{\text{OUT}} = 10\mu\text{F}$

R1525x090B

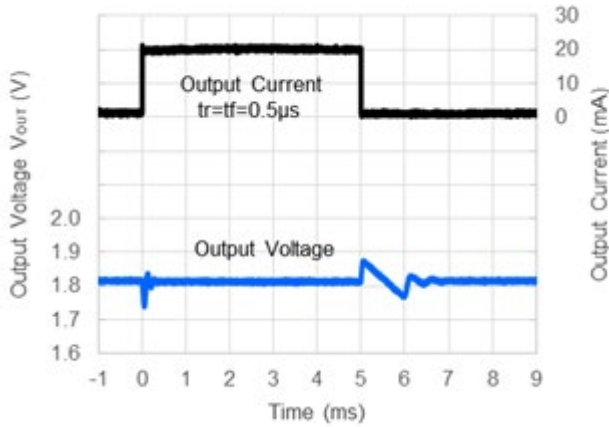


$I_{OUT} = 50 \text{ mA}$ ,  $C_{OUT} = 10\mu\text{F}$   
R1525x120B

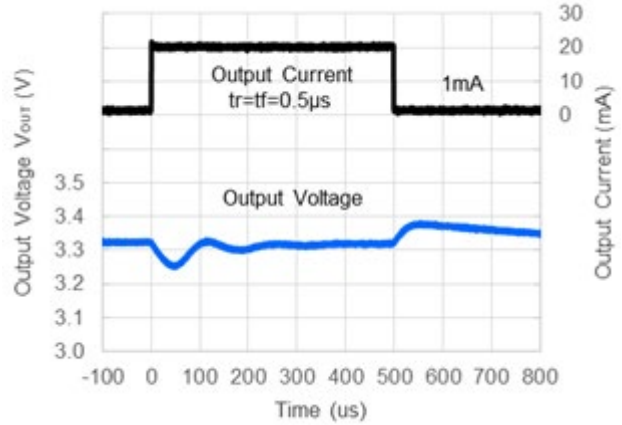


**11) Load Transient Response**

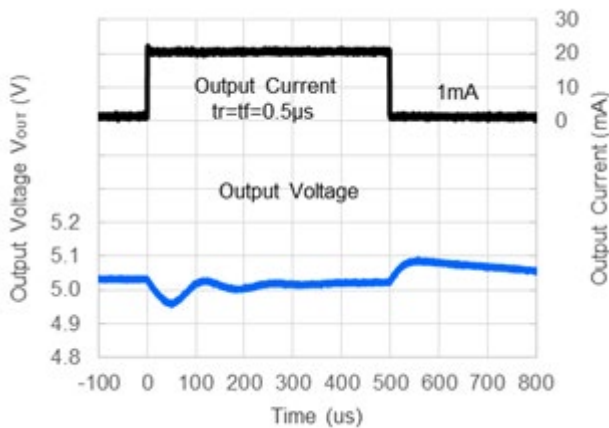
$V_{IN} = 14 \text{ V}$ ,  $I_{OUT} = 1.0 \text{ mA} \rightarrow 20 \text{ mA}$ ,  $C_{OUT} = 10\mu\text{F}$   
R1525x018B



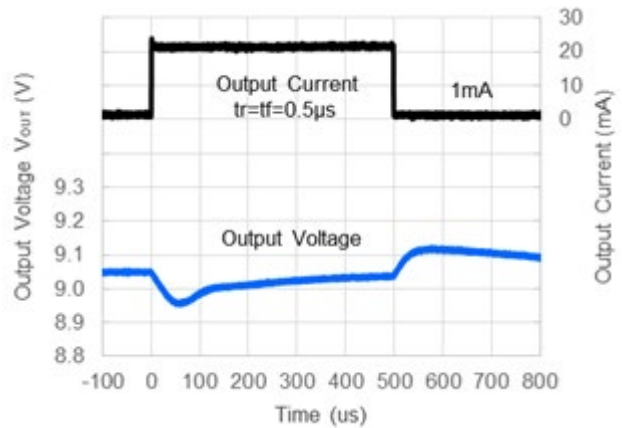
$V_{IN} = 14 \text{ V}$ ,  $I_{OUT} = 1.0 \text{ mA} \rightarrow 20 \text{ mA}$ ,  $C_{OUT} = 10\mu\text{F}$   
R1525x033B



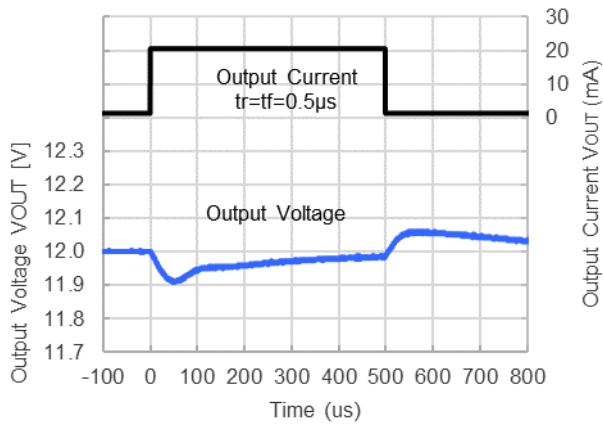
$V_{IN} = 14 \text{ V}$ ,  $I_{OUT} = 1.0 \text{ mA} \rightarrow 20 \text{ mA}$ ,  $C_{OUT} = 10\mu\text{F}$   
R1525x050B



$V_{IN} = 14 \text{ V}$ ,  $I_{OUT} = 1.0 \text{ mA} \rightarrow 20 \text{ mA}$ ,  $C_{OUT} = 10\mu\text{F}$   
R1525x090B

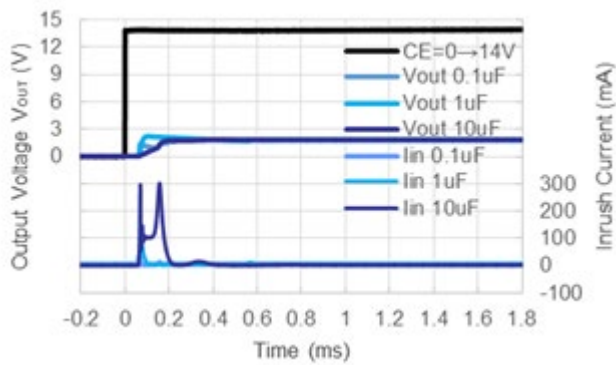


$V_{IN} = 14\text{ V}$ ,  $I_{OUT} = 1.0\text{ mA} \rightarrow 20\text{ mA}$ ,  $C_{OUT} = 10\mu\text{F}$   
R1525x120B

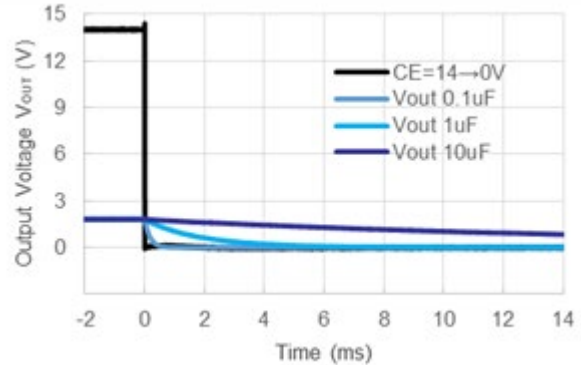


**12) CE Transient Response**

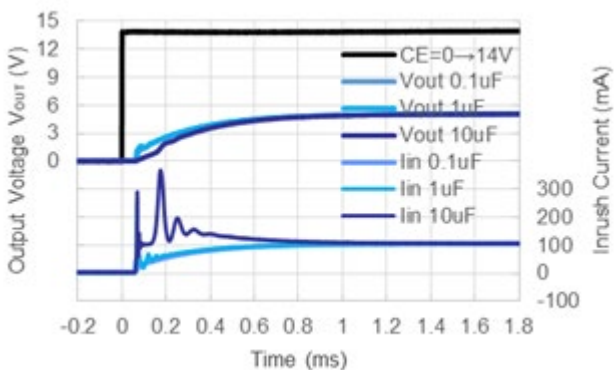
$V_{IN} = 14\text{ V}$ ,  $V_{CE} = 0\text{ V} \rightarrow 14\text{ V}$   
R1525x018B



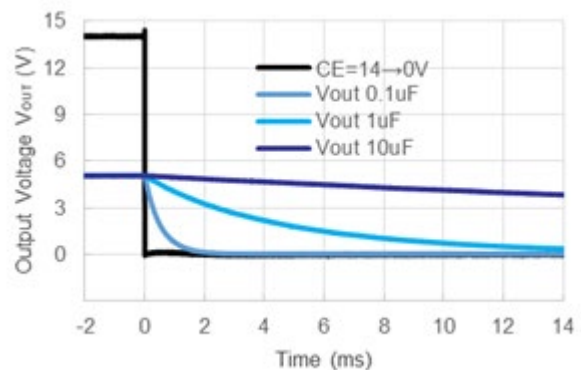
$V_{IN} = 14\text{ V}$ ,  $V_{CE} = 14\text{ V} \rightarrow 0\text{ V}$   
R1525x018B



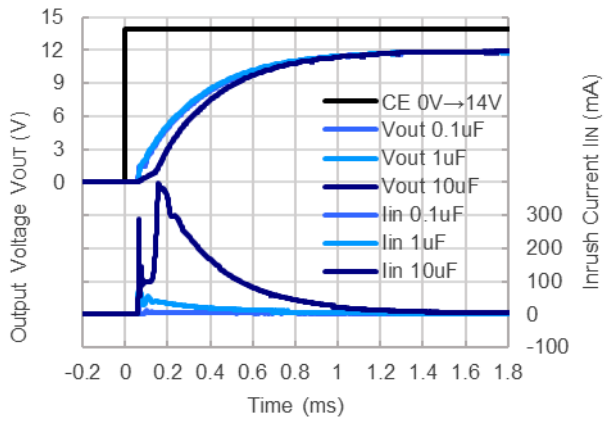
$V_{IN} = 14\text{ V}$ ,  $V_{CE} = 0\text{ V} \rightarrow 14\text{ V}$   
R1525x050B



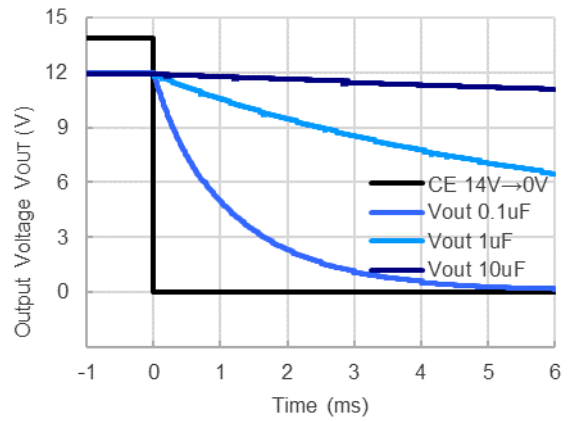
$V_{IN} = 14\text{ V}$ ,  $V_{CE} = 14\text{ V} \rightarrow 0\text{ V}$   
R1525x050B



$V_{IN} = 14\text{ V}, V_{CE} = 0\text{ V} \rightarrow 14\text{ V}$   
R1525x120B

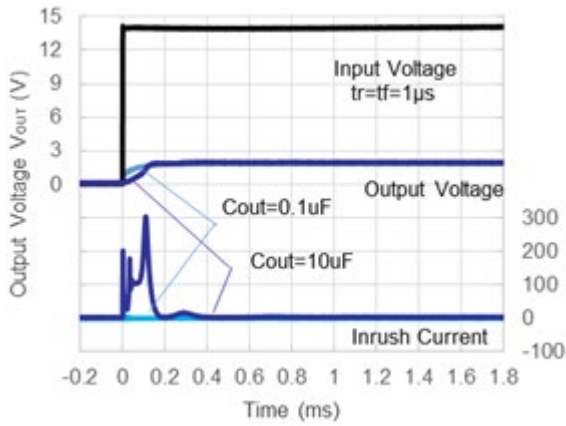


$V_{IN} = 14\text{ V}, V_{CE} = 14\text{ V} \rightarrow 0\text{ V}$   
R1525x120B

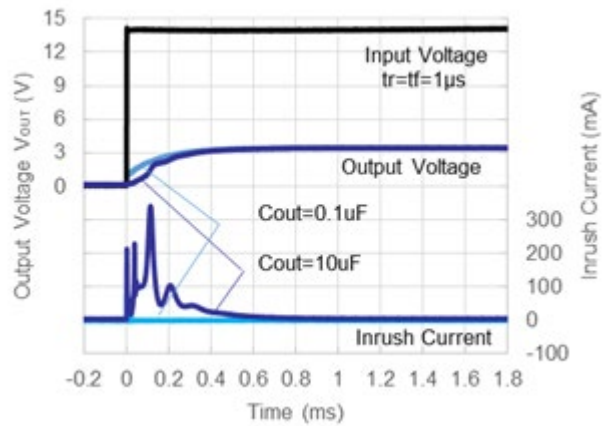


**13) Power-on Transient Response**

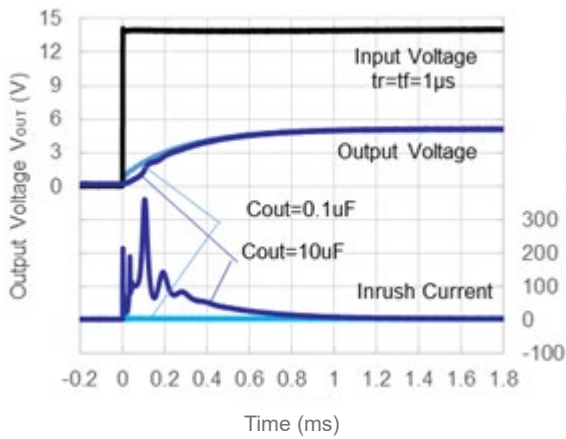
$V_{IN} = 0\text{ V} \rightarrow 14\text{ V}, V_{CE} = 5\text{ V}$   
R1525x018B



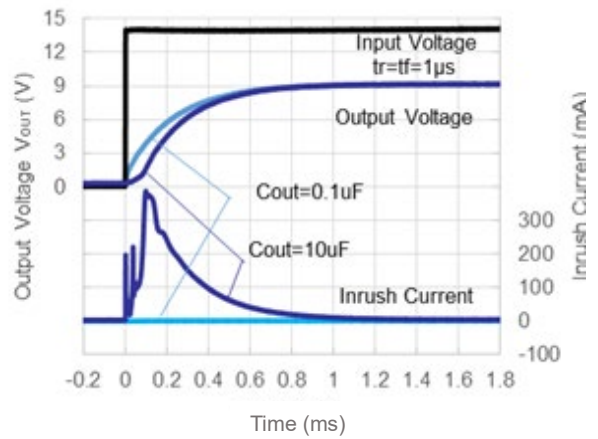
$V_{IN} = 0\text{ V} \rightarrow 14\text{ V}, V_{CE} = 5\text{ V}$   
R1525x033B



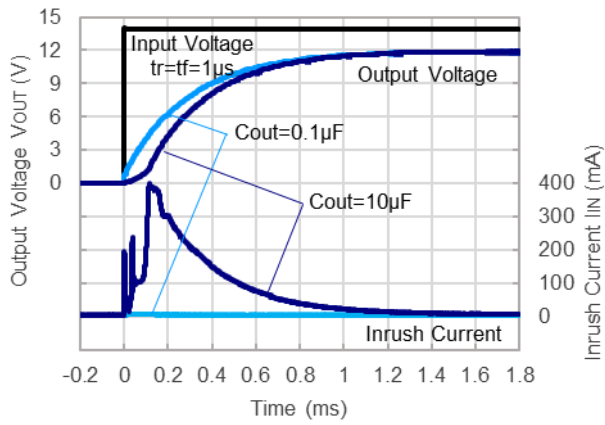
$V_{IN} = 0\text{ V} \rightarrow 14\text{ V}, V_{CE} = 5\text{ V}$   
R1525x050B



R1525x090B

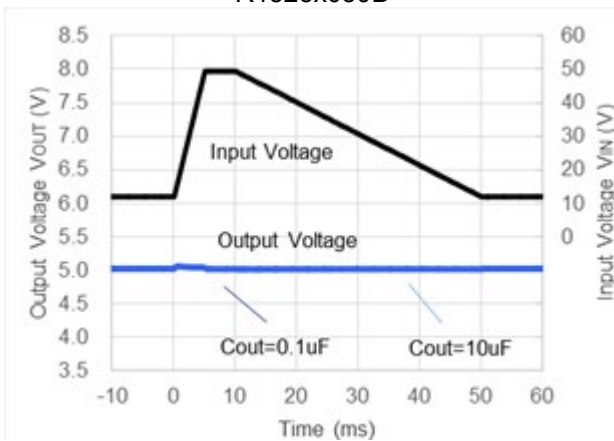


$V_{IN} = 0\text{ V} \rightarrow 14\text{ V}$ ,  $V_{CE} = 5\text{ V}$   
R1525x120B

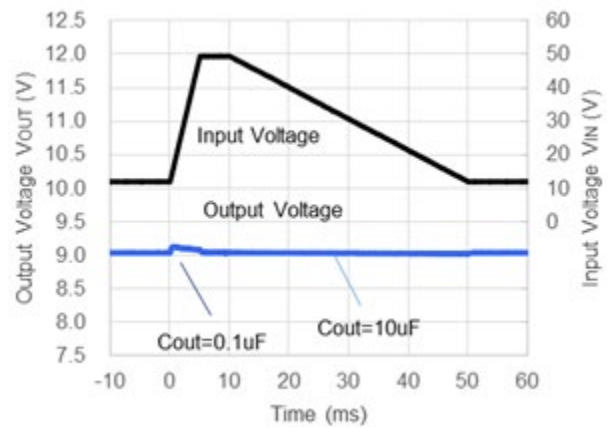


**14) Load Dump**

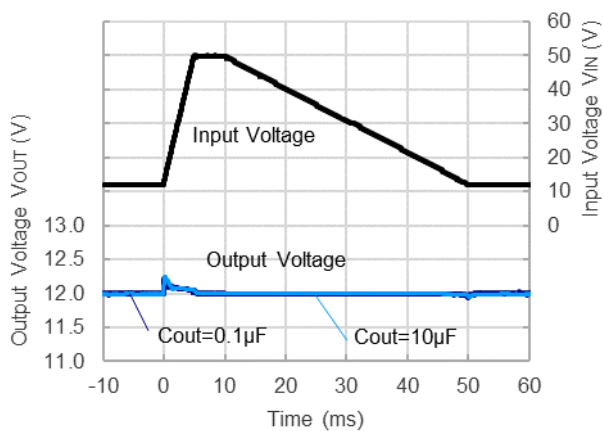
$V_{IN} = 12\text{ V} \rightarrow 50\text{ V}$ ,  $V_{CE} = V_{IN}$ ,  $I_{OUT} = 1.0\text{ mA}$   
R1525x050B



$V_{IN} = 12\text{ V} \rightarrow 50\text{ V}$ ,  $V_{CE} = V_{IN}$ ,  $I_{OUT} = 1.0\text{ mA}$   
R1525x090B



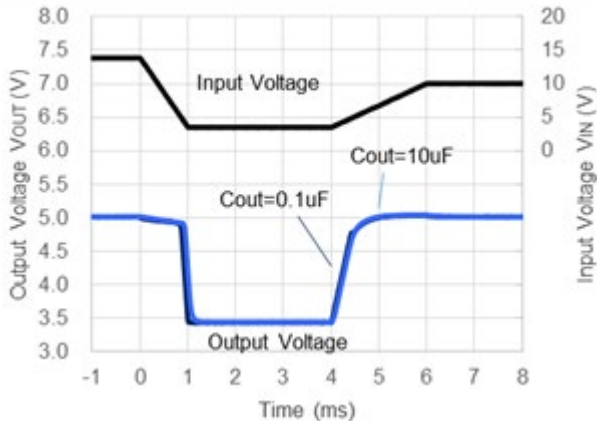
$V_{IN} = 12\text{ V} \rightarrow 50\text{ V}$ ,  $V_{CE} = V_{IN}$ ,  $I_{OUT} = 1.0\text{ mA}$   
R1525x120B



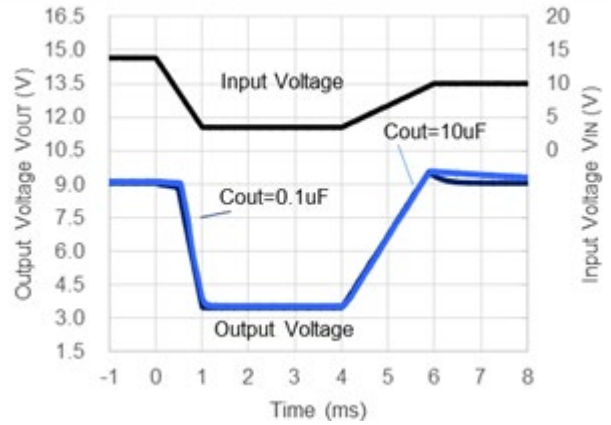


15) Cranking

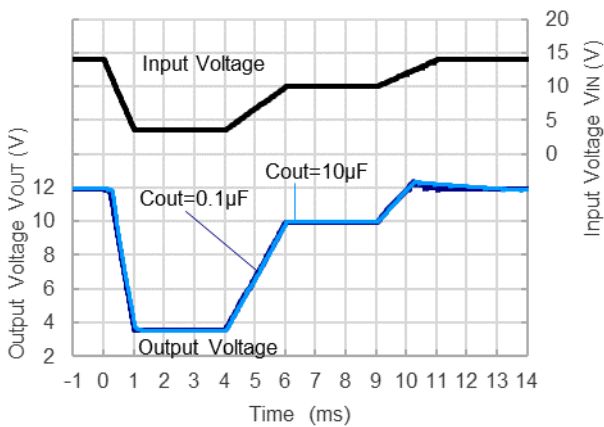
$V_{IN} = 14\text{ V} \rightarrow 3.5\text{ V} \rightarrow 10\text{ V}$ ,  $I_{OUT} = 1.0\text{ mA}$   
R1525x050B



$V_{IN} = 14\text{ V} \rightarrow 3.5\text{ V} \rightarrow 10\text{ V}$ ,  $I_{OUT} = 1.0\text{ mA}$   
R1525x090B



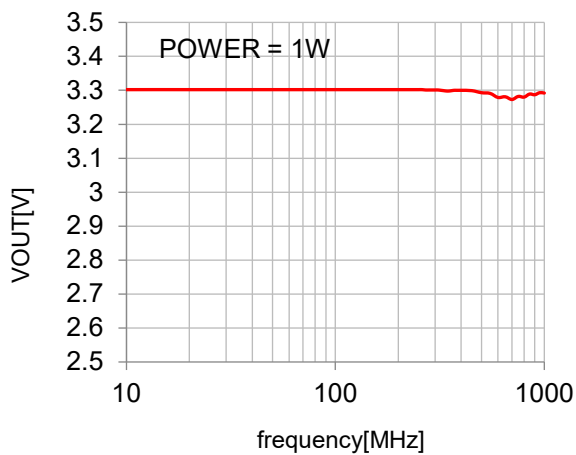
$V_{IN} = 14\text{ V} \rightarrow 3.5\text{ V} \rightarrow 10\text{ V}$ ,  $I_{OUT} = 1.0\text{ mA}$   
R1525x120B



16) DPI (VOUT Pin impressed at 1W)

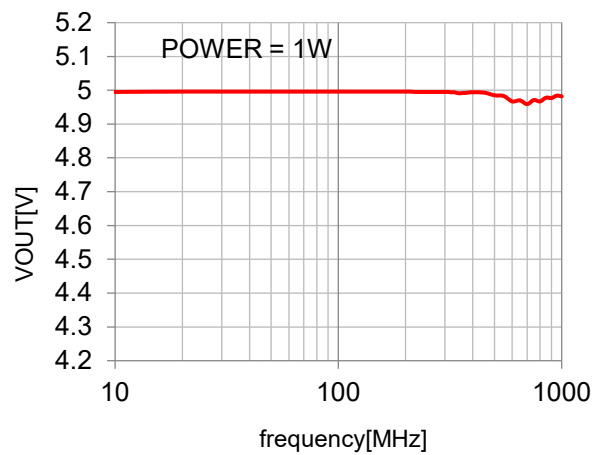
$V_{IN} = 14\text{ V}$

R1525x033B



$V_{IN} = 14\text{ V}$

R1525x050B



The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

**Measurement Conditions**

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 7 pcs

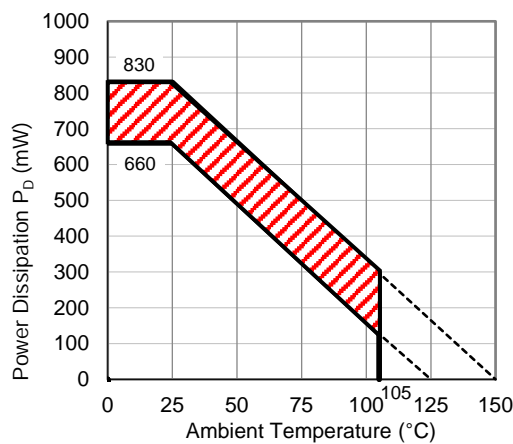
**Measurement Result**

(Ta = 25°C, Tjmax = 125°C)

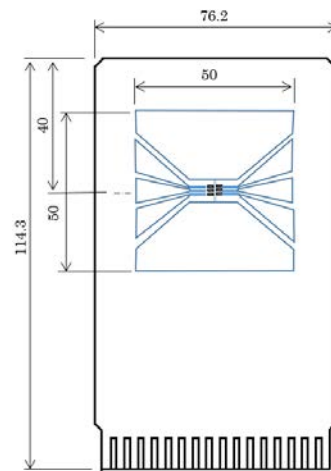
Item	Measurement Result
Power Dissipation	660 mW
Thermal Resistance (θja)	θja = 150°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 51°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



**Power Dissipation vs. Ambient Temperature**



**Measurement Board Pattern**

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years



UNIT: mm

SOT-23-5 Package Dimensions

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

**Measurement Conditions**

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 13 pcs

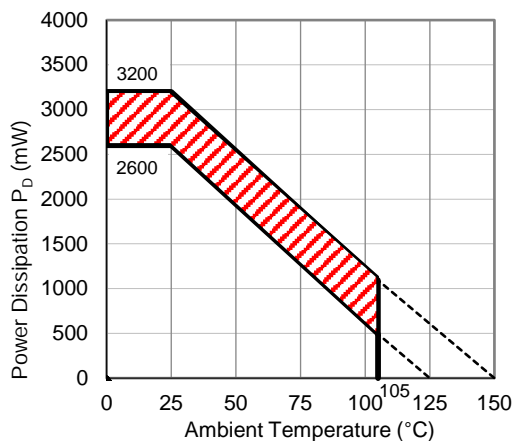
**Measurement Result**

(Ta = 25°C, Tjmax = 125°C)

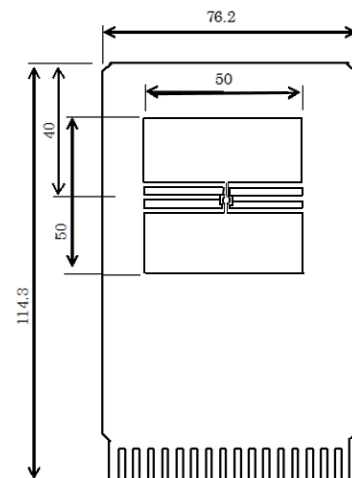
Item	Measurement Result
Power Dissipation	2600 mW
Thermal Resistance (θja)	θja = 38°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 13°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



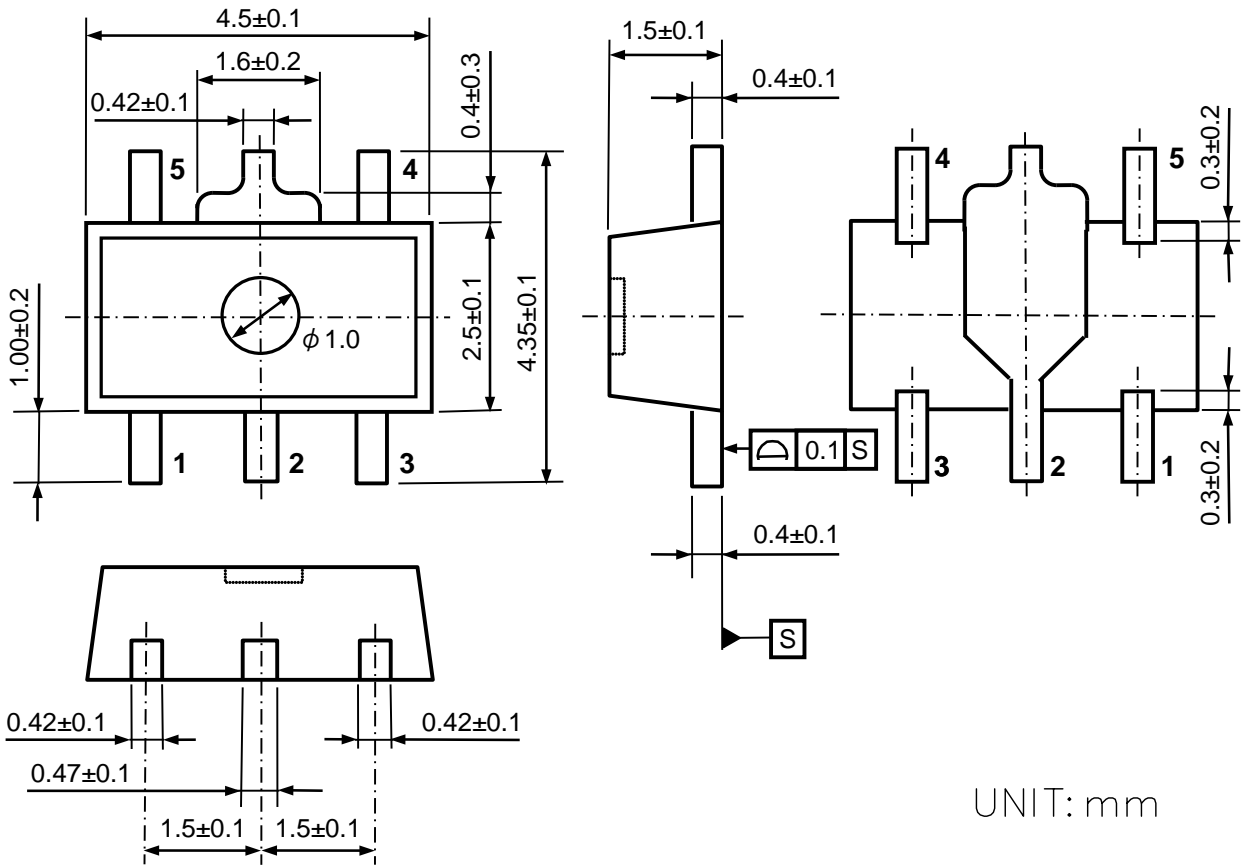
**Power Dissipation vs. Ambient Temperature**



**Measurement Board Pattern**

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years



SOT-89-5 Package Dimensions

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

**Measurement Conditions**

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 28 pcs

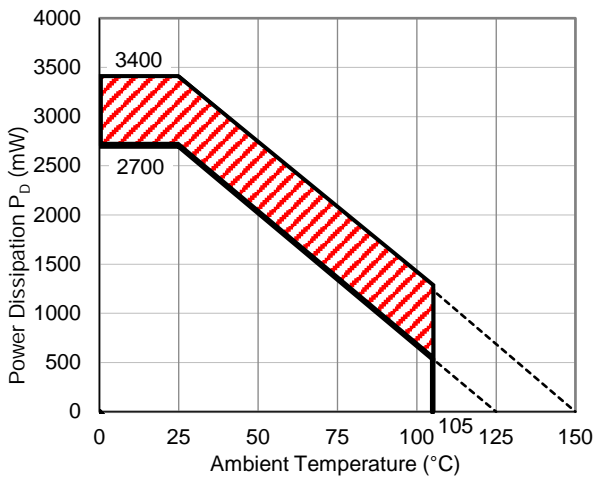
**Measurement Result**

(Ta = 25°C, Tjmax = 125°C)

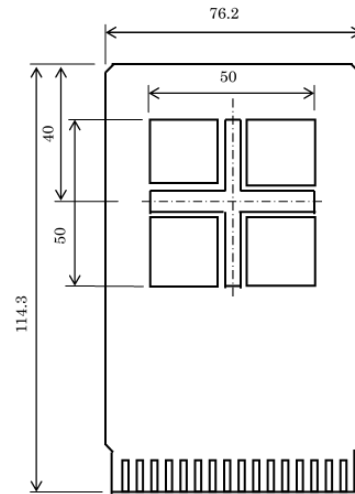
Item	Measurement Result
Power Dissipation	2700 mW
Thermal Resistance (θja)	θja = 37°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 7°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



**Power Dissipation vs. Ambient Temperature**



**Measurement Board Pattern**

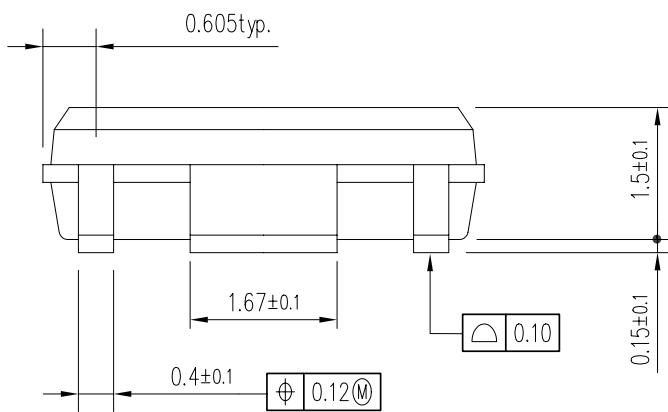
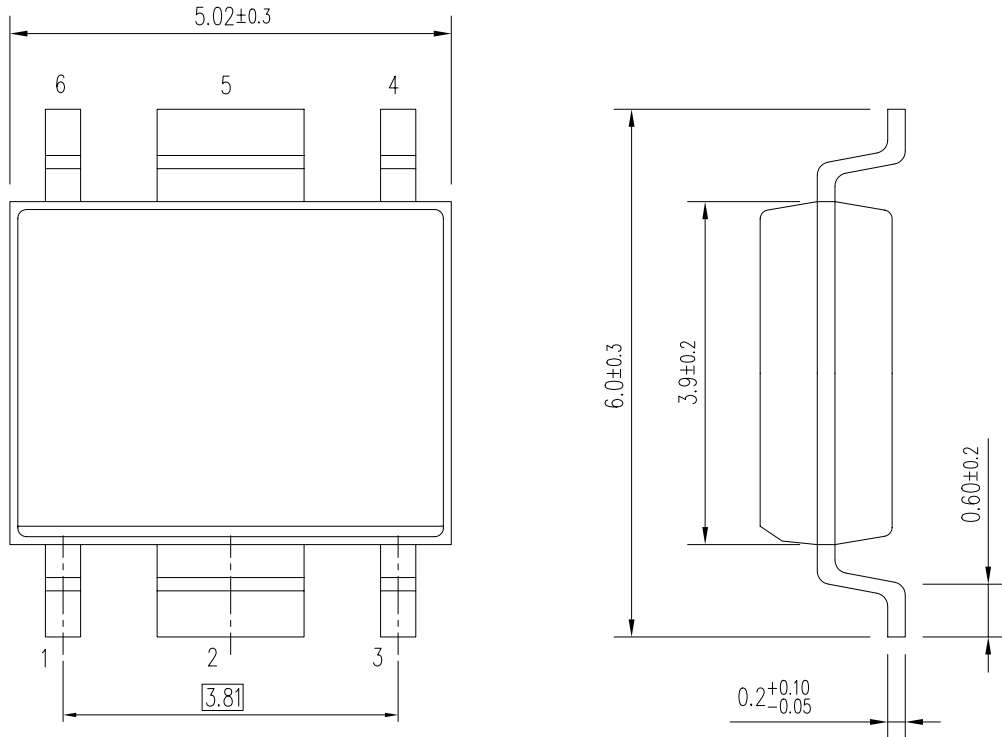
The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

# PACKAGE DIMENSIONS

# HSOP-6J

DM-HSOP-6J-JE-A



UNIT: mm

HSOP-6J Package Dimensions

# POWER DISSIPATION

# HSOP-8E

PD-HSOP-8E-(105125150)-JE-B

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

### Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 21 pcs

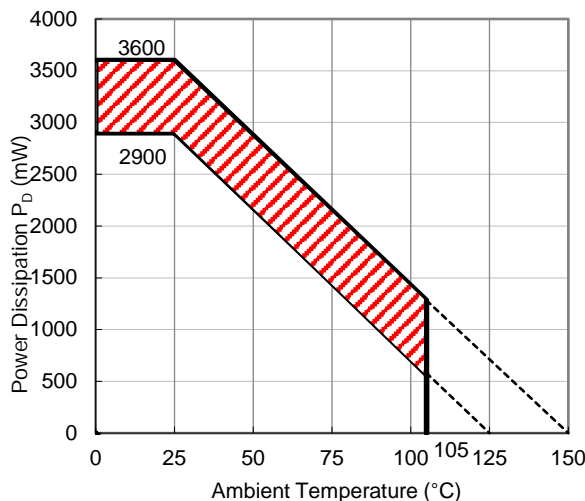
### Measurement Result

(Ta = 25°C, Tjmax = 125°C)

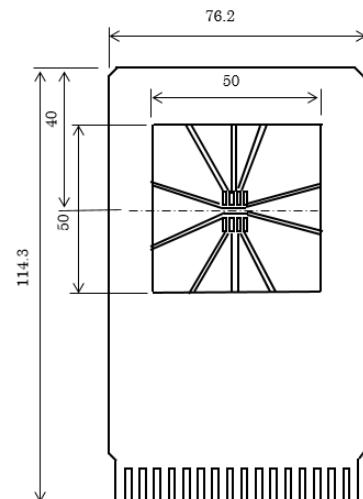
Item	Measurement Result
Power Dissipation	2900 mW
Thermal Resistance (θja)	θja = 34.5°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 10 °C/W

θja: Junction-to-ambient thermal resistance.

ψjt: Junction-to-top of package thermal characterization parameter.



**Power Dissipation vs. Ambient Temperature**



**Measurement Board Pattern**

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

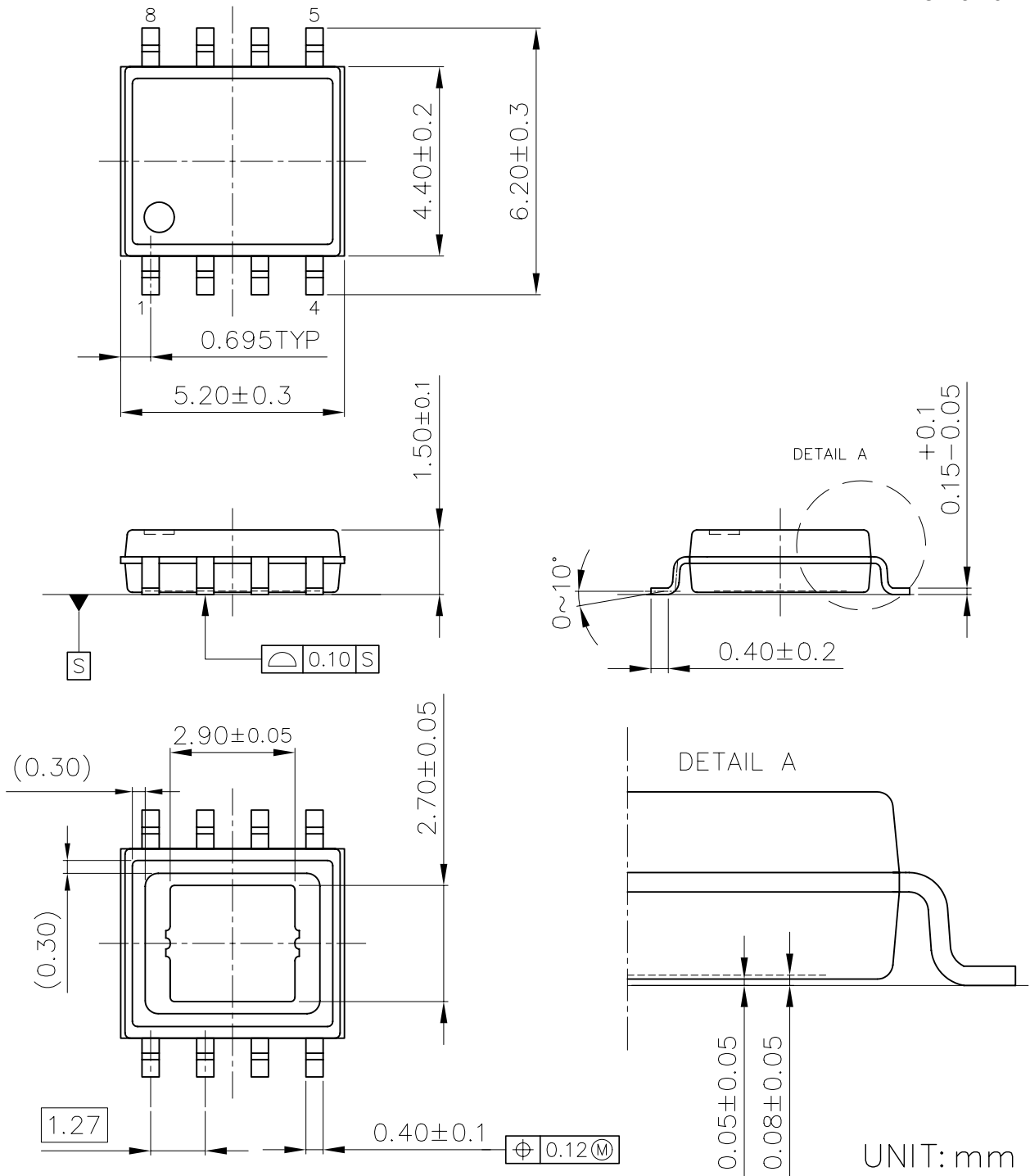
Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years



# PACKAGE DIMENSIONS

# HSOP-8E

DM-HSOP-8E-JE-B



UNIT: mm

HSOP-8E Package Dimensions

# POWER DISSIPATION

# DFN(PL)1820-6

PD-DFN(PL)1820-6-(105125150)-JE-C

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51.

### Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.2 mm × 36 pcs

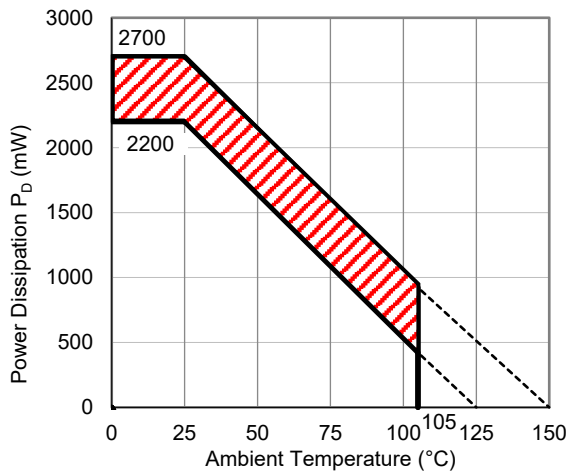
### Measurement Result

(Ta = 25°C, Tjmax = 125°C)

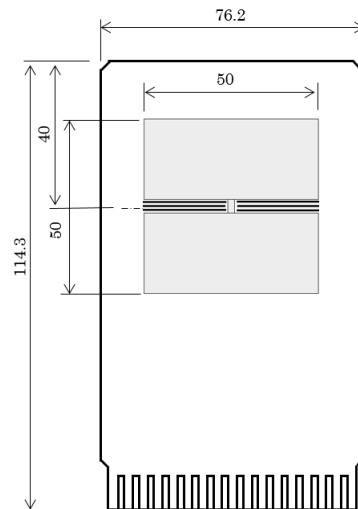
Item	Measurement Result
Power Dissipation	2200 mW
Thermal Resistance (θja)	θja = 45°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 18°C/W

θja: Junction-to–ambient thermal resistance.

ψjt: Junction–to–top of package thermal characterization parameter.



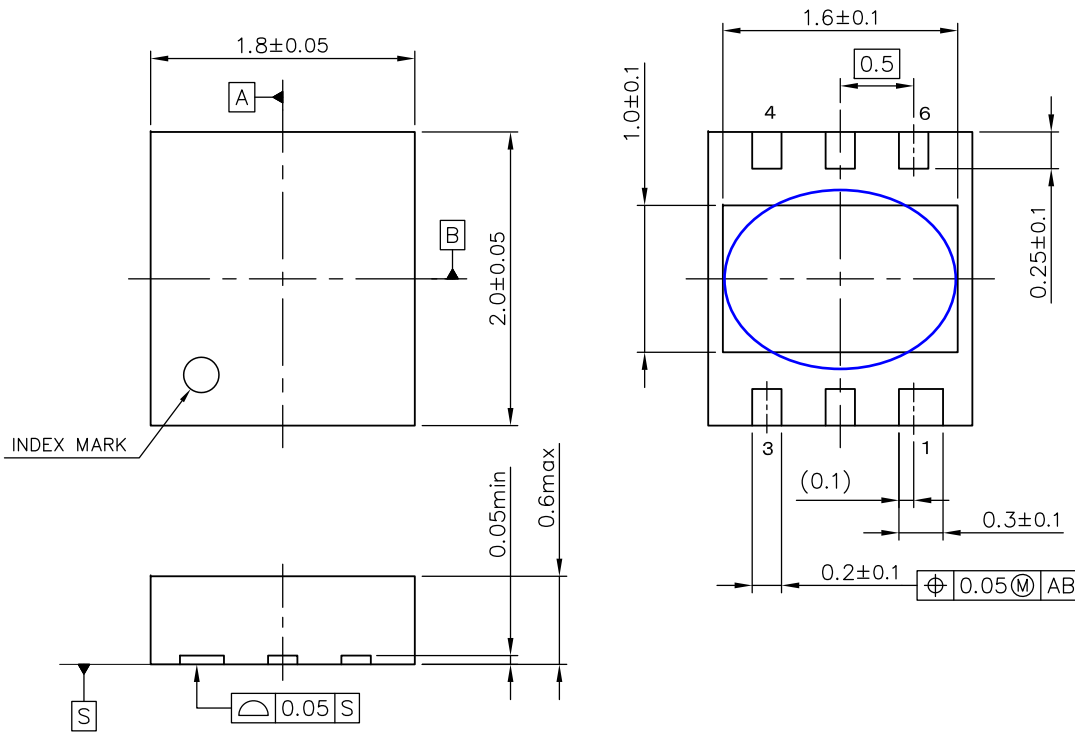
**Power Dissipation vs. Ambient Temperature**



**Measurement Board Pattern**

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years



**DFN(PL)1820-6 Package Dimensions**

\* The tab on the bottom of the package is substrate level (GND/V<sub>DD</sub>). It is recommended that the tab be connected to the ground plane/the VDD pin on the board, or otherwise be left floating.

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  - 8-2. **Quality Warranty Remedies**

When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
  - 8-3. **Remedies after Quality Warranty Period**

With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
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12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
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